

VISION

The Department of Electronics & Communication Engineering shall strive to create engineering technocrats for addressing the global challenges in relevant areas to cater the ever-changing needs of society at National and International level.

MISSION

- 1. To ensure dissemination of knowledge through effective teaching and learning in Electronics and Communication Engineering.
- 2. To excel in Research and Development activities in emerging areas.
- 3. To promote industry-institute and institute-institute linkages for sustainable development of academic, research, training and placement activities.
- 4. To establish centre of excellence in thrust areas to nurture the spirit of innovation and creativity among faculty and students.



Programme Educational Objectives (PEOs)

- 1. To be well acquainted with fundamentals of Electronics & Communication Engineering for leading a successful career in industry or as an entrepreneur or pursuing higher education.
- 2. To inculcate rational approach towards constantly evolving technologies with ethical responsibilities.
- 3. To foster techno-commercial skills for innovative solutions in Electronics & Communication Engineering or related areas.
- 4. To participate in life-long learning in the relevant domain for addressing global societal needs.

Programme Outcomes (POs)

After successful completion of B.E. (Electronics & Communication Engineering) program, the engineering graduates will be able to:

- 1. **Engineering knowledge**: Apply the knowledge of mathematics, science, engineering fundamentals, and an engineering specialization to the solution of complex engineering problems.
- 2. **Problem analysis**: Identify, formulate, review research literature, and analyze complex engineering problems reaching substantiated conclusions using first principles of mathematics, natural sciences, and engineering sciences.
- 3. **Design/development of solutions**: Design solutions for complex engineering problems and design system components or processes that meet the specified needs with appropriate consideration for the public health and safety, and the cultural, societal, and environmental considerations.
- 4. **Conduct investigations of complex problems**: Use research-based knowledge and research methods including design of experiments, analysis and interpretation of data, and synthesis of the information to provide valid conclusions.
- 5. **Modern tool usage**: Create, select, and apply appropriate techniques, resources, and modern engineering and IT tools including prediction and modelling to complex engineering activities with an understanding of the limitations.
- 6. **The engineer and society**: Apply reasoning informed by the contextual knowledge to assess societal, health, safety, legal and cultural issues and the consequent responsibilities relevant to the professional engineering practice.
- 7. **Environment and sustainability**: Understand the impact of the professional engineering solutions in societal and environmental contexts, and demonstrate the knowledge of, and need for sustainable development.
- 8. **Ethics**: Apply ethical principles and commit to professional ethics and responsibilities and norms of the engineering practice.
- 9. **Individual and teamwork**: Function effectively as an individual, and as a member or leader in diverse teams, and in multidisciplinary settings.

Department of Electronics & Communication



- 10. **Communication**: Communicate effectively on complex engineering activities with the engineering community and with society at large, such as, being able to comprehend and write effective reports and design documentation, make effective presentations, and give and receive clear instructions.
- 11. **Project management and finance**: Demonstrate knowledge and understanding of the engineering and management principles and apply these to one's own work, as a member and leader in a team, to manage projects and in multidisciplinary environments.
- **12. Life-long learning**: Recognize the need for, and have the preparation and ability to engage in independent and life-long learning in the broadest context of technological change.

PROGRAM SPECIFIC OUTCOMES (PSOs)

<u>PSO1</u>: Ability to participate successfully in competitive examinations, career advancement and higher studies with professional ethics.

PSO2: Ability to solve real world problems in Electronics and Communication Engineering using state of art techniques, along with analytical and managerial skills.



B.E. (Electronics and Communication Engineering)

		Semester-I (Gro	oup-A)				
S.No.	Sub Code	Subject Name	L	Т	Р	Hrs.	Credits
1	BSMA-401	Engineering Mathematics I	3	1	0	4	4
2	BSPH-401	Applied Physics	3	1	0	4	4
3	ESEE-401	Elements of Electrical	2	1	0	3	3
5	ESEE-401	Engineering	Z	1	0	5	3
4	ESCS-401	Elements of Computer	2	0	0	2	2
		Engineering				_	_
5	ESEC-401	Elements of Electronics	2	0	0	2	2
6	BSPH-402	Engineering Applied Physics Lab	0	0	2	2	1
0	B3F11-402	Elements of Electrical	0	0	2	2	±
7	ESEE-402	Engineering Lab	0	0	2	2	1
		Elements of Computer					
8	ESCS-402	Engineering Lab	0	0	4	4	2
9	ESEC-402	Elements of Electronics	0	0	2	2	1
9	E3EC-402	Engineering Lab	0	0	2	2	L L
		Total	12	3	10	25	20
		Semester-II A (G	roup-A)		T	Г	
S.No.	Sub Code	Subject Name	L	Т	Р	Hrs.	Credits
1	BSMA-402	Engineering Mathematics II	3	1	0	4	4
2	BSCH-401	Applied Chemistry	3	1	0	4	4
3	ESME-401	Elements of Mechanical Engineering	2	1	0	3	3
4	ESME-402	Workshop Technology and Practice	1	0	0	1	1
5	HSMC-401	English Communication and Soft Skills	1	0	0	1	1
6	BSCH-402	Applied Chemistry Lab	0	0	2	2	1
		Elements of Mechanical	0	0			
7	ESME-403	Engineering Lab	0	0	2	2	1
8	ESME-404	Engineering Drawing	0	0	4	4	2
		Workshop Technology and					
9	ESME-405	Practice Lab	0	0	4	4	2
10	HSMC-402	English Communication and Soft Skills Lab	0	0	2	2	1
11	MCCH-401	Environmental Studies	2	0	0	3	0
	MCCH-401		3 13	0 3	0 14	30	20
		Total	12	5	14	30	20
		Semester-I	L-R				
		Practical Training During Summer	0				
1	TPIN-421	Vacations (In-house) 02 weeks	0	0	40	40	1 (S/US)
' 							

Department of Electronics & Communication

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EAA-521+ +GROUP A/B/C Semester-VA S.No. Sub Code Subject Name L T P Hrs. Credits 1 PCEC-611 Digital Communication 3 0 0 3 3 2 PCEC-612 EMF & Transmission Lines 3 0 0 3 3 3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Open Elective-2 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2	कर्ममु करिए	· · · · · · · · · · · · · · · · · · ·						
1 BSMA-501 Methods Numerical and Statistical Methods 3 0 0 3 3 2 PCEC-511 Network Analysis & Synthesis 2 1 0 3 3 3 PCEC-512 Digital System Design 2 1 0 3 3 4 PCEC-513 Signals & Systems 2 1 0 3 3 6 BSBL-501 Biology for Engineers 2 0 0 2 2 1 8 PCEC-512 Digital System Design Lab 0 0 4 4 2 7 BSMA-502 Numerical and Statistical Methods Lab 0 0 4 4 2 7 BSME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 8 PCEC-522 Microprocessor & Microcontroller 3 0 0 3 3			Semest	ter-III				
1 BSMA-501 Methods 3 0 0 3 3 2 PCEC-511 Network Analysis & Synthesis 2 1 0 3 3 3 PCEC-512 Digital System Design 2 1 0 3 3 4 PCEC-513 Signals & Systems 2 1 0 3 3 5 PCEC-514 Electronic Devices & Circuits 2 1 0 3 3 6 BSBL-501 Biology for Engineers 2 0 0 2 2 1 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 6 Sub Code Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 3 PCEC-	S.No.	Sub Code	Subject Name	L	т	Р	Hrs.	Credits
3 PCEC-512 Digital System Design 2 1 0 3 3 4 PCEC-513 Signals & Systems 2 1 0 3 3 5 PCEC-514 Electronic Devices & Circuits 2 1 0 3 3 6 BSBL-501 Biology for Engineers 2 0 0 2 2 1 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 7 BSMA-502 Numerical and Statistical Methods Lab 0 0 4 4 2 7 DSMCode Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 4 PCEC-524 Analog Electronic Circuits 2 1 0 3 3 <	1	BSMA-501		3	0	0	3	3
4 PCEC-513 Signals & Systems 2 1 0 3 3 5 PCEC-514 Electronic Devices & Circuits 2 1 0 3 3 6 BSBL-501 Biology for Engineers 2 0 0 2 2 7 BSMA-502 Numerical and Statistical Methods Lab 0 0 4 4 2 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 7 BSMA-502 Regineering Mechanics 3 1 0 4 4 2 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 9 CEC-521 Analog Communication 3 0 0 3 3 1 ESME-501 Engineering Mechanics 3 0 0 3 3 4 PCEC-524 Analog Cleartonic Circuits 2 1 0 3 3	2	PCEC-511	Network Analysis & Synthesis	2	1	0	3	3
5 PCEC-514 Electronic Devices & Circuits 2 1 0 3 3 6 BSBL-501 Biology for Engineers 2 0 0 2 2 7 BSMA-502 Numerical and Statistical Methods Lab 0 0 4 4 2 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 9 Sub Code Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 4 PCEC-523 Microcontroller 3 0 0 3 3 5 HSMC-501 Principles of Management 3 0 0 4 4 2	3	PCEC-512	Digital System Design	2	1	0	3	3
6 BSBL-501 Biology for Engineers 2 0 0 2 2 7 BSMA-502 Numerical and Statistical Methods Lab 0 0 2 2 1 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 Total 14 03 06 23 20 Semester-IV-A Semester-IV-A 5.No. Sub Code Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 4 PCEC-523 Microprocessor & Microprocessor & Microporcessor & Microporcesso	4	PCEC-513	Signals & Systems	2	1	0	3	3
7 BSMA-502 Numerical and Statistical Methods Lab 0 0 2 2 1 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 Total 14 03 06 23 20 Semester-IV-A Semester-IV-A Semester-IV-A Semester-IV-A Semester-IV-A Semester-IV-A Semester-IV-A Semester-IV-A Semester-IV-A 3 0 0 3 3 4 PCEC-521 Analog Electronic Circuits 2 1 0 3 3 5 HSMC-501 Principles of Management 3 0 0 4 4 2 Microprocessor & Microcontroller Lab 0 0 4 4 2 <td>5</td> <td>PCEC-514</td> <td>Electronic Devices & Circuits</td> <td>2</td> <td>1</td> <td>0</td> <td>3</td> <td>3</td>	5	PCEC-514	Electronic Devices & Circuits	2	1	0	3	3
7 BSMA-502 Methods Lab 0 0 2 2 1 8 PCEC-515 Digital System Design Lab 0 0 4 4 2 Total 14 03 06 23 20 Semester-IV-A S.No. Sub Code Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 4 PCEC-523 Microprocessor & Microcontroller 3 0 0 3 3 5 HSMC-501 Principles of Management 3 0 0 4 4 2 7 PCEC-523 Microprocessor & Microcontroller Lab 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0	6	BSBL-501	Biology for Engineers	2	0	0	2	2
Total 14 03 06 23 20 Semester-IV-A Semester-IV-A S.No. Sub Code Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 3 PCEC-523 Microcontroller 3 0 0 3 3 4 PCEC-524 Analog Electronic Circuits Lab 0 0 4 4 2 7 PCEC-525 Microcontroller Lab 0 0 4 4 2 8 MCMH - S01 Constitution of India 3 0 0 3 0 8 MCMH - S01 Constitution of India 3 0 0 40 1 (S/US) 9 Fractional credit course/Extra Academic Activity 0 0 40 40 1 (S/US)	7	BSMA-502		0	0	2	2	1
Semester-IV-A S.No. Sub Code Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 3 PCEC-522 Analog Electronic Circuits 2 1 0 3 3 4 PCEC-523 Microprocessor & Microprocessor & Microprocessor & Microprocessor & Microprocessor & Microprocessor & Microcontroller Lab 0 0 4 4 2 7 PCEC-525 Microprocessor & Microprocessor & Microprocessor & Microprocessor & Microprocessor & Sol i 0 0 4 4 2 8 MCMH - S01 Constitution of India 3 0 0 3 0 9 EAA-521+ Industrial Training 02 weeks 0 0 40 1 (S/US) Fractional credit course/Extra Academic Activity 0 0 40 1 (S/US) Fractional credit course/Extra Academic Activ	8	PCEC-515	Digital System Design Lab	0	0	4	4	2
S.No. Sub Code Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 3 PCEC-522 Analog Electronic Circuits 2 1 0 3 3 4 PCEC-522 Analog Electronic Circuits 2 1 0 3 3 5 HSMC-501 Principles of Management 3 0 0 4 4 2 7 PCEC-524 Analog Electronic Circuits Lab 0 0 4 4 2 7 PCEC-525 Microprocessor & Microcontroller Lab 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0 8 MCMH - 501 Constitution of India 3 0 0 40 1 (S/US)			Total	14	03	06	23	20
S.No. Sub Code Subject Name L T P Hrs. Credits 1 ESME-501 Engineering Mechanics 3 1 0 4 4 2 PCEC-521 Analog Communication 3 0 0 3 3 3 PCEC-522 Analog Electronic Circuits 2 1 0 3 3 4 PCEC-522 Analog Electronic Circuits 2 1 0 3 3 5 HSMC-501 Principles of Management 3 0 0 4 4 2 7 PCEC-524 Analog Electronic Circuits Lab 0 0 4 4 2 7 PCEC-525 Microprocessor & Microcontroller Lab 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0 8 MCMH - 501 Constitution of India 3 0 0 40 1 (S/US)								
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2 PCEC-521 Analog Communication 3 0 0 3 3 3 PCEC-522 Analog Electronic Circuits 2 1 0 3 3 4 PCEC-523 Microprocessor & Microcontroller 3 0 0 3 3 5 HSMC-501 Principles of Management 3 0 0 4 4 2 7 PCEC-523 Microprocessor & Microprocessor & Microprocessor & Microcontroller Lab 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0 8 MCMH - 501 Constitution of India 3 0 0 3 0 9 Fractional credit course/Extra Academic Activity 0 0 40 1 (S/US) 6 Fractional credit course/Extra Academic Activity 0 0 40 1 (S/US) 6 Sub Code Subject Name L T P Hrs. Credits			-	-				-
3 PCEC-522 Analog Electronic Circuits 2 1 0 3 3 4 PCEC-523 Microprocessor & Microcontroller 3 0 0 3 3 5 HSMC-501 Principles of Management 3 0 0 4 4 2 7 PCEC-524 Analog Electronic Circuits Lab 0 0 4 4 2 7 PCEC-525 Microprocessor & Microprocessor & Microcontroller Lab 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0 Image: Terror Semester-IV-B Industrial Training 02 weeks 0 0 40 40 1 (S/US) Fractional credit course/Extra Academic Activity 0 0 40 40 1 (S/US) EAA-521+ +GROUP A/B/C 0 0 40 3 3 1 PCEC-611 Digital Communication 3 0 0 3 3						-	-	-
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4 PCEC-523 Microcontroller 3 0 0 3 3 5 HSMC-501 Principles of Management 3 0 0 3 3 6 PCEC-524 Analog Electronic Circuits Lab 0 0 4 4 2 7 PCEC-525 Microprocessor & Microcontroller Lab 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0 6 PCEC-525 Industrial Training 02 weeks 0 0 40 40 1 (S/US) 8 TPID-521 Industrial Training 02 weeks 0 0 40 40 1 (S/US) 9 Fractional credit course/Extra Academic Activity 0 0 40 40 1 (S/US) 9 EAA-521+ +GROUP A/B/C 9 0 3 3 1 PCEC-611 Digital Communication 3 0 0 3 3 2	3	PCEC-522	-	2	1	0	3	3
6 PCEC-524 Analog Electronic Circuits Lab 0 0 4 4 2 7 PCEC-525 Microprocessor & Microcontroller Lab 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0 6 MCMH - 501 Constitution of India 3 0 0 3 0 8 MCMH - 501 Constitution of India 3 0 0 3 0 9 Constitution of India 3 0 0 40 40 1 (S/US) 7 PCEC-521 Industrial Training 02 weeks 0 0 40 40 1 (S/US) 9 Fractional credit course/Extra Academic Activity 0 0 40 40 1 (S/US) 9 EAA-521+ +GROUP A/B/C Sub Code Subject Name L T P Hrs. Credits 1 PCEC-611 Digital Communication 3 0 0 <td>4</td> <td>PCEC-523</td> <td>-</td> <td></td> <td>0</td> <td>0</td> <td></td> <td>3</td>	4	PCEC-523	-		0	0		3
7 PCEC-525 Microprocessor & Microcontroller Lab 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0 Image: Constitution of India 3 0 0 3 0 3 0 Image: Constitution of India 3 0 0 4 4 2 8 MCMH - 501 Constitution of India 3 0 0 3 0 Image: Constitution of India 3 0 0 3 0 3 0 Image: Constitution of India 3 0 0 40 40 1 (S/US) Image: Constitution of India Semester-IV-B Image: Constitution of India 0 0 40 40 1 (S/US) Image: EAA-521+ HGROUP A/B/C Image: Constitution of India 0 0 40 1 (S/US) Image: EAA-521+ HGROUP A/B/C Image: Constitution of India 3 0 3 3 <t< td=""><td></td><td></td><td>Principles of Management</td><td></td><td></td><td>0</td><td>3</td><td></td></t<>			Principles of Management			0	3	
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8 501 Constitution of India 3 0 0 3 0 Image: Total 17 02 8 27 20 Semester-IV-B TPID-521 Industrial Training 02 weeks 0 0 40 40 1 (S/US) Fractional credit course/Extra Academic Activity 0 0 40 40 1 (S/US) EAA-521+ +GROUP A/B/C 0 0 40 40 1 (S/US) Semester-VA S.No. Sub Code Subject Name L T P Hrs. Credits 1 PCEC-611 Digital Communication 3 0 0 3 3 2 PCEC-612 EMF & Transmission Lines 3 0 0 3 3 3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Open Elective-1 3 0 0 3 3 5	7			0	0	4	4	2
Semester-IV-B TPID-521 Industrial Training 02 weeks 0 0 40 40 1 (S/US) Fractional credit course/Extra Academic Activity 0 0 40 40 1 (S/US) EAA-521+ +GROUP A/B/C 0 0 40 40 1 (S/US) Semester-VA Semester-VA Semester-VA Semester-VA Semester-VA Semester-VA S.No. Sub Code Subject Name L T P Hrs. Credits 1 PCEC-611 Digital Communication 3 0 0 3 3 2 PCEC-612 EMF & Transmission Lines 3 0 0 3 3 3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Open Elective-2 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6	8		Constitution of India	3	0	0	3	0
TPID-521 Industrial Training 02 weeks 0 0 40 40 1 (S/US) Fractional credit course/Extra Academic Activity +GROUP A/B/C 0 0 40 40 1 (S/US) S.No. Sub Code Subject Name L T P Hrs. Credits 1 PCEC-611 Digital Communication 3 0 0 3 3 2 PCEC-612 EMF & Transmission Lines 3 0 0 3 3 3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Professional Elective-1 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2			Total	17	02	8	27	20
TPID-521 Industrial Training 02 weeks 0 0 40 40 1 (S/US) Fractional credit course/Extra Academic Activity +GROUP A/B/C 0 0 40 40 1 (S/US) S.No. Sub Code Subject Name L T P Hrs. Credits 1 PCEC-611 Digital Communication 3 0 0 3 3 2 PCEC-612 EMF & Transmission Lines 3 0 0 3 3 3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Open Elective-1 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2								
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Semester-VA S.No. Sub Code Subject Name L T P Hrs. Credits 1 PCEC-611 Digital Communication 3 0 0 3 3 2 PCEC-612 EMF & Transmission Lines 3 0 0 3 3 3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Open Elective-2 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2		EAA-521+	Academic Activity	0	0	40	40	1 (S/US)
S.No.Sub CodeSubject NameLTPHrs.Credits1PCEC-611Digital Communication300332PCEC-612EMF & Transmission Lines300333OEEC-611Open Elective-1300334OEEC-612Open Elective-2300335PEEC-611Professional Elective-1300336HSMC-601Technical Communication20022						1		
1 PCEC-611 Digital Communication 3 0 0 3 3 2 PCEC-612 EMF & Transmission Lines 3 0 0 3 3 3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Open Elective-2 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2			Semester-V	V A				
2 PCEC-612 EMF & Transmission Lines 3 0 0 3 3 3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Open Elective-2 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2	S.No.	Sub Code	Subject Name	L	Т	Р	Hrs.	Credits
3 OEEC-611 Open Elective-1 3 0 0 3 3 4 OEEC-612 Open Elective-2 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2	1	PCEC-611	Digital Communication	3	0	0	3	3
4 OEEC-612 Open Elective-2 3 0 0 3 3 5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2	2	PCEC-612	EMF & Transmission Lines	3	0	0	3	3
5 PEEC-611 Professional Elective-1 3 0 0 3 3 6 HSMC-601 Technical Communication 2 0 0 2 2	3	OEEC-611	Open Elective-1	3	0	0	3	3
6 HSMC-601 Technical Communication 2 0 0 2 2	4	OEEC-612			0	0		
	5	PEEC-611	Professional Elective-1	3	0	0	3	3
	6	HSMC-601		2	0	0	2	2
7PCEC-613Analog & Digital Communication Lab00442	7	PCEC-613	Analog & Digital Communication Lab	0	0	4	4	2
8HSMC-602Technical Communication Lab00221	8	HSMC-602	Technical Communication Lab	0	0	2	2	1

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कर्मस कार्याय							
		Total	17	0	6	23	20
9*	HDEC-611	Hon's Subject-1					4
10*	HDEC-612	Hon's Subject-2					4

		Semester-V	/B				
	EAA-611+	Fractional credit course/Extra Academic Activity +GROUP A/B/C	0	0	40	40	1 (S/US)
			//				
		Semeste		-		11	Cualita
S.No.	Sub Code	Subject Name	L	T	P	Hrs.	Credits
1	PCEC-621	Linear Integrated Circuits	2	1	0	3	3
2	PCEC-622	Wireless Communication	3	0	0	3	3
3	OEEC-621	Open Elective-3	3	0	0	3	3
4	OEEC-622	Open Elective-4	3	0	0	3	3
5	PEEC-621	Professional Elective-2	3	0	0	3	3
6	HSMC-603	Engineering Economics and Entrepreneurship	3	0	0	3	3
7	PCEC-623	Linear Integrated Circuits Lab	0	0	2	2	1
8	PCEC-624	MATLAB Programming Lab	0	0	2	2	1
		Total	17	1	4	22	20
9*	HDEC-621	Hon's Subject-3					4
	1	Semester-V	I-B				
	TPID-621	Industrial Training 04 weeks	0	0	40	40	2(S/US)
	EAA-622+	Fractional credit course/Extra Academic Activity +GROUP A/B/C	0	0	40	40	1 (S/US)
	T						
		Semest	er-VII	ſ	1	1	
S.No.	Sub Code	Subject Name	L	Т	Р	Hrs.	Credits
1	PCEC-711	Digital Signal Processing	3	0	0	3	3
2	PCEC-712	Antenna and Wave Propagation	3	0	0	3	3
3	PEEC-711	Professional Elective-3	3	0	0	3	3
4	PEEC-712	Professional Elective-4	3	0	0	3	3
5	OEEC-711	Open Elective-5	3	0	0	3	3
6	PCEC-713	Digital Signal Processing Lab	0	0	2	2	1
7	PCEC-714	Antenna and Microwave Lab	0	0	4	4	2
8	PREC-711	Project Stage I and Seminar	0	0	4	4	2
		Total	15	0	10	25	20
9*	HDEC-711	Hon's Subject-4					4
	1						
		Semeste	er-VIII	I	T	T	_
S.No.	Sub Code	Subject Name	L	Т	Р	Hrs.	Credits
1	PEEC-721	Professional Elective-5	3	0	0	3	3
2	PEEC-722	Professional Elective-6	3	0	0	3	3

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AND S & HOAL	*							
3	PREC-721	Project Stage II		0	0	12	12	6
		Total		6	0	12	18	12
4*	PHEC-721	Hon's Project		0	0	08	08	4
		OR						
S.No.	Sub Code	Subject Name		L	Т	Р	Hrs.	Credits
1	INID-721	Internship in Industry		0	0	40	40	6
2	PREC-721	Project Stage II		0	0	12	12	6
		То	tal	0	0	52	52	12
3*	PHEC-721	Hon's Project		0	0	08	08	4

*For honor subjects

	Credit Structure of Undergradua	ate Engir	neering P	rogram		
S.No.	Category	L	Т	Р	Hrs.	Credits
1	Humanities and Social Sciences including Management courses	9	0	4	13	11
2	Basic Science courses	17	4	6	27	24
3	Engineering Science courses including workshop, drawing, basics of electrical/mechanical/computer etc.	12	3	18	33	24
4	Professional core courses	34	5	26	65	52
5	Professional Elective courses relevant to chosen specialization/branch	12	0	0	12	12
6	Open subjects – Electives from other technical and /or emerging subjects	15	0	0	15	15
7	Project work	0	0	12	12	6
8	Seminar/Internship/ Industrial training	0	0	204	204	13
9	Any others [Mandatory Courses and Fractional Credit Courses]	6	0	120	126	3
			Total			160

Department of Electronics & Communication

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Dilip Kumar



List of Professional Electives

		Professional Elective-I							
S.No.	Sub Code	Subject Name							
1	PEEC-611A	Pulse and Digital Switching Circuits							
2	PEEC-611B	MEMS							
3	PEEC-611C	Information Theory & Coding							
		Professional Elective-II							
S.No.	Sub Code	Subject Name							
1	PEEC-621A	Control System Engineering							
2	PEEC-621B	Telecommunication Switching Systems & Networks							
3	PEEC-621C	MOS Device Physics & Modelling							
		Professional Elective-III							
S.No.	Sub Code	Subject Name							
1	PEEC-711A	Microelectronics							
2	PEEC-711B	Optoelectronics Devices & Circuits							
3	PEEC-711C	Computer Communication & Networks							
		Professional Elective-IV							
S.No.	Sub Code	Subject Name							
1	PEEC-712A	Microwave & Radar Engineering							
2	PEEC-712B	Computer Architecture & Organization							
3	PEEC-712C	Industrial Electronics							
		Professional Elective-V							
S.No.	Sub Code	Subject Name							
1	PEEC-721A	Wireless Sensor Networks							
2	PEEC-721B	Satellite Communication							
3	PEEC-721C	VLSI Circuits							
Professional Elective-VI									
S.No.	Sub Code	Subject Name							
1	PEEC-722A	Fiber Optics Communication							
2	PEEC-722B	Electronic Measurement & Instrumentation							
3	PEEC-722C	Neural Networks & Fuzzy Logic							

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List of Open Electives

		Open Elective-I
S.No.	Sub Code	Subject Name
1	OEEC-611A	Linear Integrated Circuits
2	OEEC-611B	Digital Electronics
3	OEEC-611C	Electronic Measurement & Instrumentation
		Open Elective-II
S.No.	Sub Code	Subject Name
1	OEEC-612A	Principle of Communication Engineering
2	OEEC-612B	Optical Electronics
3	OEEC-612C	MATLAB Programming
		Open Elective-III
S.No.	Sub Code	Subject Name
1	OEEC-621A	Microprocessor and Applications
2	OEEC-621B	VLSI Technology
3	OEEC-621C	Nano Technology
		Open Elective-IV
S.No.	Sub Code	Subject Name
1	OEEC-622A	Biomedical Electronics
2	OEEC-622B	Control System Engineering
3	OEEC-622C	Electronic System Design
		Open Elective-V
S.No.	Sub Code	Subject Name
1	OEEC-711A	Digital Systems
2	OEEC-711B	Microcontroller and Embedded Systems
3	OEEC-711C	Wireless Communication

Department of Electronics & Communication



				F	1		SEC-4			·				
				L L	iemen	ts of E	lectron T	ics En	gineeri	ng P			Credit	2
				2			0			0			2	,
		Sessi	onal M				•			Ū			50	
			Semest		aminat	tion Ma	arks						50	
Cours	se	The	aim of	this c	course	is to	provide	e an ir	ntroduc	tion an	d basi	c unde	rstandi	ng of
<u>Objec</u>		semic transi circu	conduct istors an its. The ducing l	or dev nd ope course	vices v erationa e also f	iz. dio al ampl ocuses	des, bij ifiers t on kno	polar j o deve	unction lop the	transi: ability	stors, j to des	unctior ign bas	i field sic elec	effect tronic
Cours	se		Design s					equent	ial logi	c circui	ts.			
Outcomes 2. Characterize semiconductors, diodes and transistors. 3. Apply the basics of diode and transistor to analyse the operation of electron devices. 4. Design electronic circuits such as rectifiers, filters, voltage regulators, transistor amplifiers and operational amplifiers.														
Mapping of Course Outcomes with program outcomes														
	P01	PO2	PO3	PO4	PO5	PO6	P07	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	3	3	1	1	1	3	1	1	0	0	2	1	2	2
CO2	3	3	3	3	3	2	1	1	0	0	3	2	3	3
CO3	3	3	0	0	0	0	0	1	0	0	1	0	3	2
CO4	3	3	3	2	1	3	0	1	0	0	0	0	3	2
					ļ	U nit-I								8 hrs
	-		d code			•	octal, a	nd hex	adecim	al num	ber sys	stem an	d their	inter-
Logic XOR, realiza	gates XNO ation o	and fl R gat f simp	code, E ip flop es, De- le Bool n table a	s: Defi Morga ean eq	initions an's th uation eration	s, symb neorem s using	s, reali univer	ization sal gat	of ba es, intr	sic gat oductio	es usin on to K	ng univ	versal	gates;
Semio	conduc	tor de	vices: S	Semico			rials: C	e. Si. i	ntrinsio	c and ex	xtrinsic	semico	onducto	
type, applic filters	n-type ations- , L- se	e, p-n half w	junctio vave, fui ilters, π nd appl	on theo ll wave - sectio	ory an e and b on filte	d diod ridge re ers, con	les, its ectifier npariso	V-I circuit n of fil	charact s, filter ters, cl	eristic, circuits ippers a	equiva s: induc and clar	alent n ctor filte	nodel, ers, cap	diode acitor
		u	"PPI			nit-III	Daiut	., .	-, priot					8 hrs
operat	ting po	oint se	ar junct election T and N	, CB,	ansisto CE, a	r (BJT) and CO	C conf	ïgurati	ons, B	0	-			e and
						nit-IV		•						8 hrs
Amp, basic	IC741 applic	pin co ations:	ifiers (onfigura adder plifier.	ation,	Op-An	np in d	ifferent	t mode	s: inve	rting ar	nd non-	inverti	ng amp	olifier,



RECO	OMMENDED BOOKS				
Title	Author	Publisher			
1. Electronic Devices & Circuits	David A. Bell	Oxford University Press, 5 th Edition 2010			
2. Electronic Devices & Circuits	J. Millman & Halkias	McGraw Hill Education 3 rd Edition 2010			
3. Electronic Devices & Circuit Theory	Robert L. Boylsted, Louis Nashelsky	Pearson Education			
4.Digital Systems: Principles and Applications	Ronald J. Tocci	PearsonEducation			



							ESEC							
				El	ement	s of El	ectron	<u>ics En</u>	gineer	ing Lał)			
			L T P Credits											
		0 0 2 1												
Cours	se	The a	The aim of this lab is to give practical exposure to students by analyzing V-I characteristics											
Objec	ctives	of dif	f different semiconductor electronics devices and design of basic electronic circuits. This											
		lab al	ab also includes verification and testing of truth table of various logic gates and flip flops.											
Cours	Course1. Analyze and design various digital circuits using basic gates and flip flops.													
Outco			•	actical	0		0		0			1 .	L	
			01				0			configu	rations.			
			•	rcuits 1						0				
		J								gram ou	tcomes			
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	3	0	3	3	2	2	0	1	3	2	1	2	1	3
CO2	3	3	3	3	2	2	0	1	3	2	1	0	1	2
CO3	3	3	0	3	2	2	0	1	3	2	1	2	2	3
CO4	3	3	3	3	2	2	0	1	3	2	1	2	2	3

List of Experiments:

- 1. Verification of the truth tables of basic gates, e.g., 7400, 7402, 7404, 7408, 7432, 7486.
- 2. Design all other gates using NAND and NOR gates.
- 3. Design S-R flip-flop using NOR/NAND gates.
- 4. Verify the truth table of J-K flip-flop (7476), D flip-flop (7474) and T flip-flop.
- 5. To observe and analyze V-I characteristics of PN junction diode.
- 6. To observe and analyze V-I characteristics of Zener diode.
- 7. Design and analysis of half wave rectifier with capacitor filter.
- 8. Design and analysis of center tap full wave rectifier with capacitor filter.
- 9. Design and analysis of bridge type full wave rectifier with capacitor filter.
- 10. Design and analysis of Zener as a voltage regulator.
- 11. To observe V-I characteristic of PNP and NPN transistor in common base configuration.
- 12. Design and analysis of Op-Amp as an inverting amplifier & non-inverting amplifier.
- 13. Design and analysis of Op-Amp as an integrator & differentiator.
- 14. To observe V-I characteristic of JFET.
- 15. To observe V-I characteristic of MOSFET.



17: कर्मसु	TPIN-421													
					Pra	actical			n-hous	e)				
			I]	Γ		P			Credits	5	
			()		(0	4	0			1 (S/US)	
<u>Cours</u>	se	In-ho	use tra	aining	is imp	arted v	with ar	1 objec	tive to	familia	arize an	d provi	de "han	ds on"
<u>Objec</u>	<u>ctives</u>	exper	ience (on the	requisi	ite tool	ls, com	ponen	ts and	instrum	ents to	be used	in Elec	tronics
		and C	and Communication Engineering. The students will be able to present their work in											
		writte	written, oral or formal presentation formats.											
9														
	<u>Course</u> After successful completion of industrial training, the students should be able to <u>Outcomes</u> 1. understand the use of various tools, electronic components and measuring													
Outco	omes	1.				ise of	vario	us too	ols, ele	ectronic	compo	nents a	ind mea	asuring
				ument							_			
		2.	•				•		-			work sk	ills.	
		3.					-		-	ractical	-			
		4.	-				•	-				ommuni	cation.	
			Ma	apping	of Co	urse O	outcom	nes wit	h prog	gram ou	tcomes			
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	3	2	2	2	2	2	2	3	3	3	1	3	3	1
CO2	3	2	3	3	3	3	3	2	2	3	1	3	3	1
CO3	3	3	2	3	2	2	2	2	1	3	1	3	3	3
CO4	1	1	1	1	1	1	1	1	3	3	1	3	1	3



					NT-	41-		C -511	C41-	•				
				L	Ne	twork A	Analys T	sis and	Synthe	esis P		<u> </u>	Credits	
				2			1			<u> </u>			3)
		S	ession		·ks					0			50	
						ination	n Marl	K S					50	
Cours	se .								undatio	n on w	hich mos	t other		in the
<u>Objec</u>						•					in object			
0.0.00											orks and			
		-	etwork	-				J				I · · · ·		0
Cours	se					al laws	and si	mplify	the net	work us	ing reduc	ction tec	hniques	5.
Outco	mes										implifica			
		3.	Evalu	ate and	l comp	oute trar	nsient r	espons	e, stead	ly state	response,	, networ	k functi	ons.
4. Calculate two port network parameters.														
5. Synthesize networks using Foster and Cauer forms. Mapping of Course Outcomes with Program Outcomes														
	PO1	PO2	M PO3	apping PO4	g of Co PO5	Durse C PO6	Dutcon PO7	es wit	h Prog	ram Ou PO10	PO11	PO12	PSO1	PSO2
CO1	3	2	1	2	3	2	0	1	1	010	0	2	3	2
					-		_			_				
CO2	2	2	2	2	2	2	0	1	1	0	1	2	3	1
CO3	1	3	1	3	3	2	0	1	2	0	1	2	3	2
	-	•												
CO4	3	3	2	3	2	2	0	1	1	0	0	2	3	2
CO5	3	1	2	3	2	2	0	1	1	0	0	2	2	1
	I		.1	l		U	nit-I			1			12	2 hrs
Basics	s of ci	rcuit	analys	is: Tw	o tern			lement	s (resis	tor, cap	acitor ar	nd induc	ctor) an	d their
											two ter			
transfe	ormatio	on, Kii	chhoff	's Lav	vs, nod	al and i	mesh a	nalysis	•	-				
Netwo	ork the	eorem	s: Sup	perposi	tion th	eorem,	recipr	ocity th	eorem,	, Thever	nin's theo	orem, No	orton th	eorem,
Millm	an's th	neoren	n, max	imum	power	r transf	er the	orem, s	ubstitu	tion the	eorem, co	ompensa	ation th	eorem,
Telleg	gen's th	eorem	ı (for b	oth AC	C and I	DC exci	tations).						
							nit-II							2 hrs
Two p	port ne	etwork	s: Intro	oductio	on to si	ingle an	nd two	port ne	tworks	, paramo	eters of ty	wo port	networl	ks such
as imp	pedance	e, adm	ittance	e, hybr	id, trar	nsmissio	on, etc.	relatio	onship a	among c	lifferent	paramet	ers, ser	ies and
paralle	el conn	ection	s of tw	o-port	netwo	rks, cor	ndition	s for sy	mmetr	ical and	reciproc	al netwo	orks, du	ality.
Reson	ance a	and m	agneti	ically	couple	d circu	uits: 1	ntrodu	ction to	o resona	ince, seri	es resoi	nance, j	parallel
resona	ance, co	oncept	of self	f-induc	tance	and mu	tual in	ductanc	ce, couj	oling co	efficient,	magnet	tically c	oupled
circuit	s, sim	ole ser	ies and	parall	el circi	uits, dot	t conve	ention, i	ideal tra	ansform	er.			
				-		Un	it-III						12	2 hrs
Trans	sient a	and s	teady	state	analy			ts in	RL, F	RC circ	uits, ini	tial con		
consta	ints,cor	ncept	of phas	sors, ii	npeda	nce and	l admi	ttance,	analy	sis of R	L, RC a	nd RLC	C circui	ts with
		-	-		-				-		rk functi			
			-		•		•	-	-		fer funct		-	
	-			-								-		
network functions, restrictions on locations of poles and zeros in driving point functions and transfer functions, review of Laplace transform, solution of network equations using Laplace transform.														
runcu	5115, 16		л сарі		11910111	n, solut		ICT WOLL	x cyual	ions usi	ng Lapia		UIII.	

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5. Networks and Systems

New Age International

	<u>Unit-IV</u>	12 hrs							
Network synthesis: Hurwitz polynom	ials, positive real function	s, synthesis of dissipative networks,							
Foster and Cauer realization (I, II forms) for LC, RL and RC networks.									
Graph theory: Concept of network graph, tree, tree branches and links, tie-set and cut-set matrices,									
introduction to SPICE simulators and M	IATLAB for solving circui	t problems.							
RECOMMENDED BOOKS									
Title	Author	Publisher							
1. Fundamentals of Electric Circuits	Charles K. Alexander and Matthew N.O. Sadiku	Tata McGraw Hill							
2. Engineering Circuit Analysis	William H. Hayt and Jack Kemmerly	Tata McGraw Hill							
3. Network Analysis	Van Valkenburg	Prentice Hall of India							
4. Circuit and Networks: Analysis and Synthesis	A.Sudhakar and S.Palli	Tata McGraw Hill							

D. Roy Choudhary



						PCEC		a . a						
		L		Т	Digita	l Syste	em De P	sign			C	redits		
		2		1			0				U	3		
	Sessiona											50		
	End Sen	nester E	xamin	ation	Marks	5						50		
Course	This cou	-						0		0				
Objectives														
	and mod													
	be discu program					rougn	case	studi	es of	more	com	piex :	systems	s using
Course	1. Analy					and co	ombin	ationa	l syste	ems				
Outcomes											and M	loore d	configu	rations
		 Assess the performance of a given digital circuit with Mealy and Moore configuration Perform static timing analysis of the digital circuits/systems. 												
	4. Desig										forma	nce of	a giver	ı digital
	circui	ts/syste												
	DO1	Mappi PO2		Cour PO4	se Ou PO5	1		· · · ·	_			PO12	PSO1	
CO1	PO1 3	3	PO3 3	1	2	PO6	1	1	1	010	2	2	3	PSO2 2
			,	-	2	-	-	-	-	Ŭ	2	2	,	
CO2	3	3	2	1	1	1	2	1	1	0	3	2	3	2
CO3	3	3	3	3	2	2	2	1	1	0	3	2	3	3
CO4	3	3	3	1	3	2	2	1	1	0	3	2	2	3
	I		Un	it-I								1		12 hrs
Basics of D K-map, log Code conv Implementa	ic gates, C ersion, M ations usin	Combin agnitud 1g ROM	ationa le con 1, PLA	l circu nparat	uits : R ors, <i>A</i>	Ripple Applic	carry ations	adder of E	, BCE), Hig rs, Do	h spece	ed add rs, MI	er, Sub JX, DI	otractor, EMUX
modules to	design dig	gital sys		it-II						[16 hrs
Sequential	Circuits	Variou			tches	and fl	in-floi	ns and	their	conve	rsions	Univ	ersal	10 111 2
Shift Regis			• 1											Timing
issues, Setu	p and hole	d times,	opera	ting fi	requer	ncy lin	nitatio	ons, St	atic Ti	iming	Analy	vsis, St	andard	ICs for
their appli	,										gn o	f Syn	chrono	us and
Asynchron	ous sequer	ntial cire	-		and h	azards	s, haza	ard fre	e desig	gn.				101
Intro du ati	on to VIII			t-III	-ital a	retara	dania		VIID	L boo	ia lan	~110 ~ ~		12 hrs
Introduction objects, cla														
digital desi		•	-	-			-	-	-			-		
models, app	•					0113, 11	niouu	CHOIL		avioui	ai, ua	lanow	and su	uctura
models, up				t-IV	•									8 hrs
Digital log	ic families	: Chara			digita	l circu	iits: fa	n in, f	an-ou	t, pow	er dis	sipatio	n, prop	
delay, nois					0					· •		1	· • •	0
application		-	-		L), CI	MOS,	comp	arison	of cl	naracte	eristic	s of T	TL, EC	CL, and
CMOS, into	-	-				•	DOIG							
Semicondu				•	0							чком	, KAM	, Static
RAM, Dyn	amic KAN	a cell, n	nemor	y cell	, readi	ng &	writin	g opei	ation	in KA	IVI.			



RECOMM	ENDED BOOKS	
Title	Author	Publisher
1. An Engineering Approach to Digital	Fletcher William, I	3 rd Indian reprint, PHI,
Design		(1994).
2. Digital Design	Morris Mano M	3 rd Edition, Pearson
		Education (2002).
3. VHDL-Analysis and Modeling of Digital Systems	Navabi Z	McGraw Hill.
4. Fundamentals of Logic Design	Charles H. Roth Jr	4 th Edition, Jaico Publishers
		(2002).
5. VHDL for Programmable Logic	Skahill Kevin	1 st Indian Reprint, Pearson
		Education (2004).
6. Verilog HDL: A Guide to Digital Design	Samir Palnitkar	2 nd Edition, Prentice Hall
and Synthesis		PTR



							PCEC										
				L		Sigr	<u>nais &</u> T	Syste	ms	Р			Credits	2			
				2			1			0			<u>3</u>	•			
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					amina	tion N	Jarks						<u> </u>				
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	<u>sc</u> ctives				-			-		d metho				-			
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		proce		, _ upi			,										
Cour	se	-		and cla	assify c	liffere	nt type	es of si	gnals	and sys	tems that	at are co	are commonly used				
Outc		1. Identify and classify different types of signals and systems that are commonly used in engineering.															
		2. Differentiate between the properties of continuous-time and discrete-time system															
		and represent CT and DT systems in the frequency domain using Fourier analysis.															
		3. Apply transform techniques to analyse continuous-time and discrete-time signals and															
		systems. 4 Understand the basic concepts of probability and random variables															
		4. Ui	. Understand the basic concepts of probability and random variables.														
				•				• 4 1									
	PO1	PO2	PO3	PO4	PO5	rse Oi PO6	PO7	es with PO8	n Prog PO9	ram O PO10	PO11	s PO12	PSO1	PSO2			
CO1	3	3	2	2	2	1	1	1	1	0104	0	2	3	3			
COI	5	5	2	2	2	1	1	1	1	U	U	2	5	5			
CO2	3	2	2	2	3	1	1	1	1	0	0	2	3	3			
CO3	3	2	2	2	3	1	1	1	1	0	0	2	3	2			
CO4	3	3	2	2	2	1	1	1	1	0	0	2	3	2			
						Unit-l	ſ							12 hrs			
Intro	ductio	n: Def	inition	of sig				eleme	ntary	signals,	classifi	cation					
	ns, pro			-		~j~	,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		j ,	8,							
•	· •	•	•		and Di	screte	-time I	LTI sys	stems.	their pr	operties						
	•					Unit-I			,	1	1			12hrs			
Four	ier ser	ies re	presen	tation	of sig	gnals:	Fouri	er ser	ies rep	oresenta	tion of	contin	uous-tin	ne and			
discre	ete-time	perio	dic sig	nals, p	roperti	es of c	ontinu	ous-ti	me and	discret	e-time l	Fourier	series.				
Four	ier trai	nsform	a: Cont	tinuou	s-time	Fourie	r trans	form o	of perio	odic and	l aperio	dic sign	als, pro	perties			
of co	ntinuou	ıs-time	Four	ier tra	nsform	, disc	rete-ti	ne Fo	urier t	ransfor	m of p	eriodic	and ap	eriodia			
	ls, conv										Ĩ		•				
					I	J nit-Il	Ι							12 hrs			
Lapla	ace trai	nsforn	n (LT)	: One-s	sided L	aplace	transf	form (I	LT) of	commo	n signal	s, impo	rtant the	orems			
-	ropertie					-					-	•					
and p	se Lan	lace t	ransfo	rm : In	verse]	LT, so	lution	s of di	fferent	ial equa	ations u	sing LT	, bilate	ral LT			
-	sc Lap		(D	OC													
Inver	n of cor	nverge	nce (R	00).													
Inver region	n of cor					Unit-I								12 hrs			
Inver region Rand	n of cor l om sig	nal th	eory: (Concep	ot of pro	obabili	ty, ran			es, comr of rando			ution fu	nction			

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Rayleigh (PDF), mean, variance and PDF of the sum of random variables, correlation between two random variables.

Random processes: Introduction, classification, correlation, and auto correlation, stationary andergodic process.

RECOMMENDED BOOKS							
Title	Author	Publisher					
1. Signals and Systems	Alan V. Oppenheim, Alan S. Willsky	Pearson Education Limited, (2013)					
2. Signal Processing and Linear Systems	B P Lathi	Oxford University Press, (2003)					
3. Signals and Systems	T. Rawat	Oxford University Press, (2010)					
4. Signals and Systems	Simon Haykin, Barry Van Veen	John Wiley & Sons, (2007)					



कर्मसु के																
					FL	atron	PCE(Circu	ita						
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<u>Obje</u>	<u>ctives</u>		-									on to sp	-	-		
										e of BJ	T, FET	s, UJT o	on the b	asis of		
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Cour			-			-		micon	ductor	physic	s for 1	ntrinsic	trinsic and extrinsic			
Outco	omes				nd their				1 /	1. 1		1.4		•, ,•		
2. Understand basics of various semiconductor diodes, BJ							es, BJI	s and th	eir qua	itative						
and quantitative analyses.							anation	and wa	lein a							
3. Analyze the performance of FETs based on their operation of the second and enclose and the second second the second se							-		-	aadam						
4. Understand and analyze special purpose diodes and their circuits.							ipplicatio		liouen							
Mapping of Course Outcomes with Program Outcomes																
	PO1	PO2		PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2		
CO1	3	3	1								2					
CO2	3	3	2	3	1	1	2	1	1	0	0	2	3	2		
CO3	3	3	2	3	1	1	2	1	1	0	0	2	3	2		
CO4	3	3	1	2	1	1	2	1	1	0	0	2	3	2		
						Unit	t-I					I		12 hrs		
Semi	condu	ctor r	hysics:	The e	nergy l			n cryst	al, cha	rge carr	iers in s	emicond				
												rier drift				
condu	ictivity	and	mobility	y, carri	er lifet	time, P	oisson	's and	contin	uity equ	uation, I	Hall effe	ct.			
						Unit	-II							12 hrs		
The I	P-N ju	nctio	n theor	y: P-N	l juncti	ion equ	uilibriu	im con	dition	, contac	t potent	tial, equi	librium	Fermi		
level,	electr	ic fiel	ld, spac	e char	ge at j	unctio	n, qua	litative	theor	y of P-	N junct	ion, P-N	junctio	on as a		
		-			-				-	-		of V-I				
		-	pletion a	and dif	ffusion	capac	itance	, juncti	on bre	eakdowi	n mecha	nism, di	ode swi	tching		
	cteristi															
Speci SCR.	al pur	pose	devices	s: Vara	actor d	iode, 7	Funnel	diode	, Scho	ottky ba	rrier die	ode, LEE), photo	odiode		
						Unit-	III							12 hrs		
comp config biasir	onents guratio ig: nee	, mo ons, ir d for ∣	odes of nput, ou biasing,	oper oper oper oper oper oper oper oper	ration, haracte bias, c	comi eristics ollecto	mon 6 8, BJT or feedl	emitter specif back bi	, con fication las, em	nmon ns, DC nitter fee	base a and A edback l	ion, tran nd comn C load 1 pias, coll	non co ine, tra ector - e	llector nsistor emitter		
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in V_{BE} and β , thermal runaway, thermal stability, transistor as an amplifier, small signal low																

feedback bias, voltage divider bias, bias stabilization, stability factor, stabilization against variations in V_{BE} and β , thermal runaway, thermal stability, transistor as an amplifier, small signal low frequencyhybrid π model of transistor, voltage gain, power gain and current gain, expressing gain in decibels, r_e transistor model, h-parameters, frequency response of BJT amplifier, switching times.

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Page 20

Dilip Kumar J.S. Ubhi



Uni	it-IV		12 hrs					
Junction field effect transistor: Basic n channel and p channel JFET operation, its V-I								
characteristics.								
Metal oxide semiconductor field effect transistor: Construction, operation and its								
characteristic. FET biasing, UJT.								
RECOMMENDED BOOKS								
Title	Author	Publish	ler					
1.Semiconductor Physics and Devices	Donald A. Neamen	Tata McGraw-H	611					
2. Electronic Devices & Circuits	J. Millman & C Halkias	McGraw Hill Education 3 ¹						
		Edition 2010						
3.Microelectronic Circuits	Adel S. Sedra,	Oxford Press	6 th Edition					
	Kenneth C. Smith	2013						
4. Solid State Electronics Devices	Ben G Streetman &	PHI 6 th edition, 2	2013					
	Sanjay Banerjee							



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Cour	se	The	aim of	of this lab is to verify and design of basic digital electronics circuits. It includes										
Obje	ctives													
			families and programmable logic devices.											U
Cour	se		1. Analyze and implement various logic gates and Boolean functions.											
	omes	2.Design and analyze combinational digital circuits.												
			3.Design and analyze sequential digital circuits.											
			4.Design memories and programmable logic devices.											
			~-8			F0-		0						
			Map	oping	of Cou	irse O	utcom	es wit	h Prog	gram O	utcome	S		
	PO1	PO2	PO3	PO4	PO5	PO6	P07	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	2	3	3	3	2	1	0	1	3	2	1	2	2	3
CO2	2	3	3	3	2	1	2	1	3	2	1	2	2	3
	-					_		_		_	-	-	-	
CO3	2	3	3	3	2	3	0	1	3	2	1	2	2	3
CO4	2	1	3	3	2	3	2	1	3	2	1	2	2	3

List of Experiments:

PART-A

- 1. Introduction to Digital Electronics lab-nomenclature of digital ICs, specifications, study of the datasheet, concept of V_{cc} and ground.
- 2. To verify De-Morgan's Theorem and Implementation of the given Boolean function using logic gates in both SOP and POS forms.
- 3. To realize half/full adder and half/full subtractor using basic/universal gates.
- 4. To realize parallel adder/subtractor using IC 7483.
- 5. To verify BCD to excess-3 code conversion using NAND gates.
- 6. To convert Gray code to binary number and binary number to Gray code.
- 7. Implementation of 4x1 multiplexer and 1x4 demultiplexer using logic gates. To implement the arithmetic circuits half adder, half subtractor, full adder and full subtractor using multiplexers.
- 8. To design and verify the operation of magnitude comparator.
- 9. Verification of state tables of RS, J-K, T and D Flip-Flops using NAND Gates with timing diagrams.

*Experimentation work to be supported by simulated results

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PART-B

- 1. To design and implement a circuit for a 2 bit parallel adder using NAND gates only.
- 2. To design and implement the 4-bit synchronous counter.
- 3. To design and implement the 4-bit asynchronous counter.
- 4. VHDL code for Half/Full adder.
- 5. VHDL behavioral description of 4-bit ALU. The circuit performs two arithmetic and two logical operations that are selected by 2-bit input. The four operations are ADD, SUB, AND and OR.
- 6. VHDL program to count number of one's in 10-bit binary number.
- 7. VHDL code for 8:3 encoder.
- 8. VHDL code for positive edge triggered T-flip flop.
- 9. VHDL code for 8-bit SISO shift register.

*Experimentation work to be supported by simulated results

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			Sessional Marks 50															
			End Se	emester	: Exam	inatior	ı Mark	S			50							
CourseThe course emphasizes on the use of essential analytical tools and the communication systems, understand various analog communication											0							
Objec	communication systems, understand various analog co FM transmission and reception circuits, analog puls									-	-							
						-		cuits, a	inalog	puise i	nouura		iiiique	s and				
Cour	noise in communication systems.Course1. Gain knowledge about the fundamental conc											of vari	ous a	nalog				
Outcomes communication systems.																		
	2. Design the AM, SSB, FM and PM transmission a									. Design the AM, SSB, FM and PM transmission and reception circuits.								
			3. Analyze the performance of amplitude and frequency modulated systems and															
			design of PAM, PWM and PPM systems.															
			4. Understand practical implementation issues and evaluate fundamental communication system parameters including noise.															
									<u> </u>									
			-		of Cour				U									
	PO1	PO2	PO3	PO4	PO5	PO6	PO7											
								PO8	PO9	PO10		PO12	PSO1					
CO1	3	2	1	1	2	2	2	PO8 1	0	PO10 0	PO11 2	PO12 2	PSO1 3	PSO2 2				
CO1 CO2	3	2 3	1 3	1 3	2 2	2 2												
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CO2	3	3	3	3	2	2	2	1	0	0	2 2	2 2	3 3	2 3				
CO2 CO3	3	3	3	3	2 2 2 2	2 2 2	2 2 2	1 1 1	0 0 0	0 0 0	2 2 0	2 2 2	3 3 3 3	2 3 3 2				
CO2 CO3 CO4	3 3 3	3 3 3	3 1 3	3 1 3	2 2 2 2	2 2 2 Unit-I	2 2 2 2	1 1 1 1	0 0 0	0 0 0	2 2 0 0	2 2 2 2	3 3 3 3 1	2 3 3 2 2 hrs				
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CO2 CO3 CO4 Analo modu wave,	3 3 3 og mo ilation, , conce	3 3 dulati	3 1 3 on tech	3 1 3 niques ectrum modula	2 2 2 : Introd of AM tion, th	2 2 Unit-I uction wave, A eory of	2 2 2 to modu AM pow	1 1 1 ulation, ver calc	0 0 0 , need c culation odulatio	0 0 0 of modu as, AM i on, mat	2 2 0 1ation, modula themati	2 2 2 theory ation wi	3 3 3 3 of amp th a cor lysis of	2 3 2 2 hrs litude nplex f FM,				

AM transmission: Basic principle of AM generation, square law modulation, low level and high-level modulation, grid modulated class-C amplifier circuit (Vander Bijl modulation), plate modulated class-C amplifier circuit, suppressed carrier AM generation (balanced modulator) diode ring modulator, product modulator.

Unit-II12 hrsFM transmission: FM generation methods: generation of FM by direct method, basic reactance
modulator, varactor diode modulator, indirect generation of FM by Armstrong method; frequency
stabilized AFC transmitter system, pre-emphasis circuit, stereophonic FM transmitter system.SSB transmission: Introduction, advantages of SSB transmission, generation of SSB, filter method,
phase shift method, Hilbert transform, representing SSB signals in terms of Hilbert transforms, SSB
modulator using a Hilbert transform, third method, forms of amplitude modulation, pilot carrier system,
independent sideband system (ISB), vestigial sideband system (VSB).

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Unit-III 12 hrs								
AM reception: Tuned radio frequency (7)		eterodyne receiver						
characteristics. RF amplifier, Image frequen	· · ·	•						
conversion and mixer circuits, tracking and		-	• • •					
detector with AGC, distortion in diode detectors, double heterodyne receiver, coherent AM detection, AM receiver using a phase locked loop (PLL).								
FM reception : Introduction, block diagram of FM receiver, amplitude limiter, de-emphasis circuit,								
	_		-					
basic principle of FM detection, slope detector, balanced slope detector, Foster-Seely phase discriminator, ratio detector, FM detector using PLL, zero crossing detector as a frequency								
demodulator, stereo FM receiver.								
SSB reception: SSB product demodulator, balanced modulator as SSB demodulator, SSB envelop								
detection receiver, pilot carrier SSB receiver, SSB double heterodyne receiver, ISB receiver, modern								
communication receiver.								
Unit-	IV		12 hrs					
Analog pulse modulation techniques: In		itude modulation						
PAM, flat-top PAM, sampling theorem, fre	· 1 1							
time modulation (PTM), pulse width modula								
modulation, generation and detection of PAI			ni), puise coue					
Noise : Introduction, external noise, internal			se sources, shot					
		1						
	noise, transit time noise, noise in reactive circuits, noise temperature, noise bandwidth, effective input noise temperature, noise figure, noise figure calculations, noise in analog modulated systems, SNR							
calculation for AM and FM.								
RECOMMENDED BOOKS								
Title Author Publisher								
1. Electronic Communication SystemsKennedy, G.Tata McGraw-Hill								
		$(2008) 4^{th}ed$						

1. Electronic Communication Systems	Kenneuy, O.	
		(2008) 4 th ed
2. Communication Systems	Haykin, S.	John Wiley & Sons
		(2009) 4 th ed.
3. Principles of Communication Systems	Taub, H&Schilling	John Wiley & Sons
4. Electronic Communication Systems	Wayne Tomasi	Pearson Education
		(2011), 5 th ed



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<u>Obje</u>	ctives	of m	ultista	ge am	plifier	by co	upling	in dif	fferent	ways.	To stud	dy diffe	rent fee	edback		
			configurations, oscillators, power amplifiers and tuned amplifiers.													
Cour	60		1. Analyze the low and high frequency response of BJT, MOSFET.													
Outco																
Oute																
 Design multistage amplifiers and various coupling techniques. Design and analyze feedback singuity and assillators. 																
4. Design and analyze feedback circuits and oscillators. Mapping of Course Outcomes with program outcomes																
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	PO1	PO2	PO3	PO4	PO5	PO6	P07	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2		
CO1	3	3	3	2	1	2	2	1	0	0	2	2	3	2		
CO2	3	3	3	2	1	2	0	1	0	0	0	2	1	2		
CO3	3	3	2	3	1	2	2	1	0	0	1	2	3	2		
CO4	3	3	2	2	1	2	1	1	0	0	1	2	3	2		
	l		1	I	I	Unit	·I	L		I				12 hrs		
Singl	e stag	e BJT	' amp	lifiers	: Anal	ysis o	f trans	sistor a	amplifi	ier circ	uit usi	ng h-pa	rameter	s, CE		
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Feedl	back a	mplifi	ers: Pr	operti	es of n			back, f	our ba	sic feed	iback to	opologie				
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Oscil	current-series, current-shunt, voltage-series and voltage-shunt feedback amplifiers. Oscillators- The oscillation criteria, Wien bridge, phase shift, LC tuned oscillators, crystal oscillators,															
astabl	astable multivibrator.															



Unit-IV			12 hrs							
Output stages and power amplifiers: Classifica	ation of output stages, ana	lysis of class-	A output stage,							
class-B output stage, class AB output stage, class C output stage, harmonic distortion.										
Tuned amplifiers: Basic principle, inductor	r losses, amplifiers wit	th multiple t	uned circuits,							
synchronous and stagger tuning, class C tuned an	mplifier.									
RECOMM	RECOMMENDED BOOKS									
Title Author Publisher										
1.Microelectronic Circuits	Adel S. Sedra,	Oxford Pres	ss 6 th Edition							
	Kenneth C. Smith	2013								
2. Integrated Electronics	Millman & Halkias	Tata Mc	Graw -Hill							
Education										
3. Electronics devices and circuit theory	Robert L Boylestad &	Pearson Edu	cation							
	Louis Nashelsky									



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CO2	3	3	2	1	1	2	2	1	0	0	3	2	3	3
CO3	3	3	3	3	2	2	2	1	0	0	3	2	3	3
CO4	3	3	3	2	3	2	2	1	0	0	3	1	2	3
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memory Progra Timing Counter Interru Paralle Mappec	mmin diagra and T pts: 80 l input 1 I/O, S uction	g using um of th Fime De 085 inte t/outpu Serial (u to 8051	s 8085 the instruction elays, S errupts, it and i using SI	microp ructions tack and restart nterfac [D and contro	devices process (a fev d Subro instruc cing ap SOD p <u>U1</u> llers &	s MPU. or: Ins outine, <u>nit-II</u> tions, a plications ins and <u>nit-III</u> Progr	truction ples). ddition ons: I/(RIM, S	n set o Assem al I/O D Devi SIM In ng usir	of 808. ably la conce ice Inte astruct	5 micro inguage pts & p erfacing ions) an	process progra processe g-I/O M nd Para	sor, Ad amming [1] es. Iapped I llel data [1] ller: Pir	dressing with ex 2 hrs I/O and I transfer 2 hrs n descrip	mode ample Memor , tion an
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RECO	RECOMMENDED BOOKS										
Title	Author	Publisher									
1.Microprocessor Architecture- Programming & Applications with 8085/8080A	Ramesh S Gaonkar	5 th Edition, Penram International Publishing									
2.Introduction of Microprocessors & Microcomputers	Ram B	4 th Edition, Dhanpat Rai Publisher (P) Ltd.									
3.The 8051 Microcontroller an Embedded Systems	d M.Mazidi, JG Maizidi	Pearson Education									
4.An introduction to Intel family of Microprocessors	James L Antonakes	3 rd Edition, Pearson Education									
4.The 8051 Microcontroller	Kenneth J. Ayala	Pearson Education									



]	PCEC-	524						
					Ana	log Ele	ctronic	s Circu	its Lab)				
				L			Т		Р			Credits		
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Cour	se	This lab includes the analysis of analog electronic circuits using hardware kits as									as wel	l as on		
<u>Obje</u>	<u>ctives</u>	ORC	ORCAD spice simulator. It also includes the study of response of multistage amplifiers under											
			various coupling techniques. Further in this lab student will observe the frequency response of various amplifiers.											
Cour	se	1. Analyze the frequency response of various coupling amplifiers.												
	comes 2. Analyze the frequency response of FET amplifier.													
			•	ne class	•	+		-		nplifier.				
			•	rious fe		-			0	1				
			M	lapping	of Cou	irse Ou	itcome	s with I	Program	n Outc	omes			
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CO2	3	3	2	2	3	2	1	1	3	2	1	2	2	2
CO3	3	2	2	3	1	2	1	1	3	2	1	2	1	1
CO4	3	2	2	3	2	2	1	1	3	2	1	2	1	2

List of Experiments:

Note: Experiments based upon hardware using hardware kits and rest using simulation with the help of simulation packages

- 1. To measure the h-parameters of CE configuration.
- 2. To determine the voltage gain of a two stage RC coupled amplifier.
- 3. To plot frequency response characteristics of Transformer coupled amplifier.
- 4. To plot frequency response characteristics of direct coupled amplifier.
- 5. To study the gain and frequency response of CS FET amplifier.
- 6. To plot frequency response of a tuned voltage amplifier and to calculate its resonant frequency.
- 7. To study the double ended tuned amplifier.
- 8. To study the class A power amplifier and find its efficiency.
- 9. To study the class B power amplifier and find its efficiency.
- 10. To study the cascode amplifier.
- 11. To study the concept of feedback in voltage amplifier.
- 12. To study the RC phase shift oscillator and measure its frequency of operation.
- 13. To study the LC oscillator and measure the frequency of operation.
- 14. To plot the frequency response of a Darlington amplifier. Calculate gain and bandwidth.
- *Compare the results of each aim of experiment with ORCAD spice simulation.



Microprocessor & Microcontroller LabLTPCredits0021Course ObjectivesThis lab includes programming part of microprocessor and its interfacing to different devices. It includes various programs to perform specific tasks i.e. addition, so multiplication and many more. Students will be interface microprocessor 8085 kit to va peripheral devices such as RS-232C, 8155/8255.Course Outcomes1. Perform various arithmetic and sorting operations with the help of microprocessor.Outcomes2. Interface 8155/8255 with 8085 and 8051. 3. Interface with various peripheral devices such as external keyboard, printer, 8253, per computers using RS232C. 4. Implement serial communication and interface external devices with 8085 and 8051Mapping of Course Outcomes with Program OutcomesPO1PO2PO3PO4PO5PO6PO7PO8PO9PO10PO11PO12PS01PCO133220132123	PCEC-525														
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CO4 3 3 2 3 2 2 1 1 3 2 1 2 3	3 3	.04 3	3 2 3	3 2	2 1	1	3	2	1	2	3	3			

List of Experiments:

PART-A

- 1. 2's compliment of 8-bit number.
- 2. 2's compliment of 16-bit number.
- 3. Program to shift a block of data from one memory location to another.
- 4. Multiplication by two, employing bit rotation.
- 5. Addition of two 16-bit numbers.
- 6. Interface ADC chip with microprocessor kit and verify its operation.
- 7. Interface DAC chip with microprocessor kit and verify its operation.
- 8. Interface an external 8253/8254 to the microprocessor kit at the address given. Hence,
 - a) generate a pulse train of specified duty cycle at the given output line,
 - b) operate as a: N counter,
 - c) Count a train of pulses for a given duration.
- 9. Interface seven segment display through 8279.
- 10. Use the SOD line to generate a square wave of the specified duty cycle at a given frequency.

Department	of Electro	onics & (Communication
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PART-B

- 1. Write a program to toggle all the bits of port 1 by sending to it the values 55H and AAH continuously. Put a time delay in between each issuing of data to port 1.
- 2. Multiply 25 by 10 using the technique of repeated addition.
- 3. Write a program to add the first 10 natural numbers.
- 4. Write a program to add two BCD numbers.
- 5. Write a program to perform the subtraction of two numbers.
- 6. Write a program to perform the division of two numbers.
- 7. Write a program using 8051 to split a byte into two nibbles and show results.
- 8. Create a square wave that has a high portion of 1085 μ S and a low portion of 15 μ S. Assume XTAL = 11.0592 MHz Use Timer 1.
- 9. Write the following programs:
 - a) Create a square wave of 50% duty cycle on bit 0 of port 1.
 - b) Create a square wave of 66% duty cycle on bit 3 of port 1.
- 10. Assuming XTAL =22 MHz, write a program to generate a pulse train of 2 seconds period on pin P2.4. Use Timer 1 in mode 1.
- 11. Design a counter for counting the pulse of an input signal. The pulse to be counted is fed to pin3.4. XTAL = 22MHz.
- 12. Design a circuit to interface ADC with microcontroller.
- 13. Design a circuit to interface DAC with microcontroller.
- 14. Design a circuit to interface LCD with microcontroller.
- 15. Design a circuit to interface keyboard with microcontroller.

Department of Electronics & Communication



	TPID-521													
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		to un	to understand various practical issues and latest trends in the field. The students will be											
		able t	able to troubleshoot various engineering faults related to their respective fields. They will											
		be ab	be able to learn ethical management practices.											
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CO2	3	2	3	3	3	3	3	2	2	3	1	3	3	1
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PCEC-611 Digital Communication														
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<u>Objec</u>	tives			-			-			-			system	
		provide in-depth knowledge of digital modulation schemes. It emphasizes performance analysis of digital communication system in the presence of not												
			calculating the probability of error for matched filter Receiver and various dig											
			modulation techniques.											
Cours	<u>'0</u>													
Outco		1. Understand the theoretical aspects of digital communication system useful for today's multidisciplinary applications.												
Outco	mes		 2. Gain knowledge about various data formats for digital data transmission. 											
			 Gain knowledge about various data formats for digital data transmission. Analyze the generation and detection of various digital modulation schemes. 											
		4. Compare the performance of different types of digital pulse and band pass												
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	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10		PO12	PSO1	PSO2
CO1	2	2	2	2	3	2	0	1	0	0	0	2	2	2
CO2	3	2	2	3	3	2	1	1	1	0	1	2	3	3
CO3	1	2	1	2	1	2	1	1	0	1	1	1	3	3
CO4	3	3	2	2	3	2	1	1	1	0	1	2	3	3
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pulse code modulation (DPCM), need of predictor, delta modulation (DM), adaptive delta modulation														

(ADM), comparison of PCM, DPCM and DM.

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12 hrs

Line coding schemes: Power spectral density (PSD) of sequence of random pulses, power spectral density of digital data, introduction to line codes and its properties, unipolar, polar and bipolar signalling formats, NRZ& RZ modulation formats, ON-OFF signalling, AMI and Manchester coding and their power spectra, comparison among various line codes, pulse shaping.

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the state										
	<u>Unit-III</u>	12 hrs								
Digital modulation techniques	: Digital modulation forma	ts, binary amplitude shift keying (BASK)								
modulator, coherent and non-coherent ASK detection, binary phase shift keying (BPSK) transmitter,										
coherent BPSK detection, diff	coherent BPSK detection, differential PSK, quadrature phase shift keying modulation (QPSK)									
transmitter and receiver, offset QPSK, M-ary BPSK, quadrature amplitude modulation (QAM), binary										
frequency shift keying (BFSK) transmitter, non-coherent FSK detector, coherent FSK detector, M-ary										
FSK, minimum shift keying (MSK) and Gaussian minimum shift keying (GMSK), power spectral										
analysis and comparison of signal constellations for digital modulation techniques.										
Unit-IV 12 hrs										
Optimal reception of digital signal: Introduction, baseband signal receiver, probability of error for the										
baseband signal, optimum receiver for baseband and bandpass signals, optimum filter transfer function,										
matched filter and its probability of error, coherent system of signal reception (correlation receiver).										
Error calculations for digital modulation techniques: Probability of error for BPSK, effect of										
imperfect phase synchronization	and imperfect bit synchro	nization on probability of error in AWGN								
channel, probability of error cald	culations for QPSK, QASK	and FSK schemes, use of signal space for								
calculation of error probability, 1	elationship between bit erro	or rate (BER) and symbol error rate (SER).								
	RECOMMENDED B	OOKS								
Title	Author	Publisher								
1. Principles of	Goutam Saha, Herbert	Tata McGraw Hill Education Private								
Communication Systems	Taub, Donald Schilling	Limited, 3rd Edition, 2008								
2. Communication Systems	Simon Haykin, Michael	John Wiley & Sons Publication, 5th								
	Moher	Edition, 2009								
3. Digital Communications	Bernard Sklar	Pearson Education Limited, 2014								
4. Modern Analog and Digital	Bhagwandas Pannalal	Oxford University Press, 2010								
Communication Lathi, Zhi Ding										

John G. Proakis, Masoud

Salehi

5. Digital Communication

System



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CO2	3	3	2	1	2	2	2	1	0	2	0	1	3	3	
CO3	3	1	1	0	2	1	1	1	0	3	2	2	3	3	
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Transmission lines: Introduction, basic principles, termination of lines with load, voltage and current distribution, characteristic impedance, propagation constant, attenuation constant, phase constant, reflection coefficient, VSWR, open and short-circuited transmission lines and their impedances, stub matching, types of high frequency transmission lines, smith charts.

RECOMMENDED BOOKS										
TitleAuthorPublisher										
1. Elements of Electromagnetics	M Sadiku	Oxford University Press								
2. Electromagnetics	J A Edminister	Schaum's Series								
3. Electromagnetics	Kraus	McGraw Hill								
4. Electromagnetic Fields and Waves	K D Parsad	Parkash Publications								
5. EM waves & Radiating	Jordan, Balmain	Prentice Hall								
6. Electromagnetic	W H Hayt	McGraw Hill								

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Active	e filters	s: First	order a	and sec	ond or	der filt	er, higł	ner orde	er low-	pass fil	lter, sec	ond or	der hig	gh pas
ilter.	band pa	ass filte	r, wide	band-	pass fil	ter. baı	nd rejec	t filter	, all-pa	ss filter	ſ .			



Wave generator: Square wave generator, triangular wave generator, saw tooth wave generator and voltage-controlled oscillator, comparator, zero crossing detector, Schmitt trigger, window detector, V to F and F to V converters, A to D and D to A converters, peak detector.

Unit-IV12 hrsSpecialized IC applications: IC 555, pin configuration, block diagram, application of 555 as
monostable and astable multivibrator, operating principles & applications of 565PLL.Voltage regulators: Fixed voltage regulators, adjustable voltage regulators, switching regulators.

RECOMMENDED BOOKS											
TitleAuthorPublisher											
1. Op Amps & Linear Integrated circuits	Ramakant Gayakwad	Pearson Education									
2. Fundamental of Microelectronics	B Razavi	Wiley India									
3. Linear Integrated Circuits	D. Roy Choudhary	New Age International									
4. Design with Operational Amplifiers and Analog Integrated Circuits	Sergio Franco	Tata Mc-Graw Hill									



OEEC-611B															
Digital Electronics															
				L			T			Р			Credits	5	
				3			1			0		4			
			Sessio	nal M	arks								50		
						amina	tion M	Iarks					50		
Cour	se		The ai	im of t	his co	urse is	to int	roduce	basic	postula	tes of B	oolean	express	ions and	
<u>Obje</u>	ctives		analyz	ze the	desig	n of c	combir	nationa	l circu	uits, se	quential	l circuit	ts, digit	tal logic	
			famili	es, sen	nicond	luctor 1	memoi	ries and	d prog	rammat	ole logic	device	s.		
Cour	se		1. Uno	derstar	d vari	ous log	gic gat	es and	desigr	n simple	e combi	national	circuits	3.	
Outc	omes		2. Des	sign an	d anal	yze see	quentia	al digit	al circ	uits.					
3. Identify and distinguish digital logic families.															
4. Elaborate the concept of semiconductor memories and programmable										le logic					
devices.															
		-	-							-	am Out				
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	
CO1	3	3	3	1	2	2	0	1	0	0	0	2	3	3	
CO2	3	3	3	1	2	2	2	1	0	0	0	2	3	3	
CO3	2	3	3	1	2	2	0	1	0	0	1	2	3	3	
CO4	2	1	2	1	2	2	2	1	0	0	1	2	3	3	
						Uni	t-I			1	1	1	12 hr	S	
minir and i	nizatio mplen	on of l nentat	Boolear	n expro addei	ession	using	K-map	o (up to	o six v	ariables	s), revie	w of log	gic gates	ions and s, design r, digital	
						Unit	-II							12 hrs	
Flip-	flops:	Latch	es, S-R	R flip-f	lop, Jł	K flip-f	flop, ra	ace aro	ound co	onditior	n, maste	r slave t	flip-flop	o, D & T	
			citation												
						<u>Unit</u>	III							12 hrs	
Counters & shift registers: Design with state equations, ripple counters, design of modulo-n ripple counter, pre-settable counters, up-down counter, decade counter, design of synchronous and asynchronous counters, design of shift registers with shift-left, shift-right & parallel load facilities, universal shift registers.Unit-IV12 hrs															
Unit-IV12 hrsDigital logic families: Characteristics of digital circuits: fan in, fan-out, power dissipation, propagation delay, noise margin, transistor-transistor logic (TTL), types of TTL gates, tristate logic & its applications, emitter coupled logic (ECL), CMOS, comparison of characteristics of TTL, ECL, and CMOS, interfacing of logic families.Semiconductor memories: Memory organization, ROM, PROM, EPROM, EEPROM, RAM, Static RAM, dynamic RAM cell, memory cell, reading & writing operation in RAM.															



RECOMMENDED BOOK											
Title	Author	Publisher									
1. Digital Design	Morris Mano	PHI, 4 th edition									
2. Digital System Principles & Applications	R J Tocci	РНІ									
3. Digital Integrated Electronics	Taub Schilling	Tata McGraw Hill Education									
4. Integrated Electronics	Millman & Halkias	Tata McGraw Hill Education									
5. Digital Computer Electronics	Malvino Brown	Tata McGraw Hill Education									
6. Modern Digital Electronics	R P Jain	Tata McGraw Hill									



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				Electr L	onic N	leasu	remen T	ts and	Instru P	umenta	tion	Cre	dits			
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		Sessi	onal N	•			•		•			50				
					amina	ation N	Aarks				50					
Cour	se	Aim of the course is to study the basics of unit, dimensions										tandard	s. It also	o gives		
<u>Obje</u>	ctives	deep	insigh	t to PN	/MC i	nstrum	ent and	d bridg	ges. It d	discusse	s as to l	now the	analog	data is		
	converted to digital and vice versa. It also discusses the CRO and concept of sign											signa				
generator and analyzer. Course 1. Explain various types of errors introduced in measurements. Outcomes 2. Understand the working of PMMC and other instruments. 3. Understand bridge theory, working of A/D and D/A converters and their applications																
					-	•	-									
4. Describe the working of CRO, signal generators and analyser's and apply for measurements																
measurements. Mapping of Course Outcomes with Program Outcomes																
	PO1	PO2	PO3	PO4	PO5	PO6	P07	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2		
CO1	1	2	0	1	2	2	0	1	0	0	0	2	2	1		
CO2	0	3	2	1	2	2	2	1	0	0	0	2	2	1		
CO3	0	3	2	1	2	2	0	1	0	0	1	2	2	1		
CO4	0	3	2	1	2	2	2	1	0	0	1	2	2	3		
						Unit-I				•				12 hrs		
										etric pr						
-					•					ds. mea			-			
-										precisio			-			
-										tical ar	alysis.	PMMC	2 instr	ument		
gaiva	nomete	a, DC	annne	lei, DC		Unit-I								12 hrs		
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										stance n						
										nductan						
					<u> </u>	U nit-II	Ι							12 hrs		
	0	U								A/D co			-	simple		
										thod rai						
										c, D/A	convers	ion tech	nnique,	digita		
	of ope	ration,	pertor	rmance				J/A co	nverto	ors.						
	•				L L	Unit-IV	V							13 h		
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mode	: CRT			-	•					illoscop			nt of v	oltage		
mode CRO freque	: CRT ency, a	nd pha	se by	CRO,	oscillo	scope j	probes	, oscill	oscope	e specifi	cations	and per	nt of v forman	oltage ce.		
mode CRO freque Signa	: CRT ency, a	nd pha rator,	ise by (analyz	CRO, o zer and	oscillo l reco i	scope j r ders: :	probes sine wa	, oscill ave, no	oscope on-sinu	-	cations ignal an	and per d functi	nt of v forman on gene	ce. erators		



RECOMMENDED BOOKS											
Title	Author	Publisher									
1. Electronic Instrumentation and Measurements	David A. Bell	2nd Ed., PHI, New Delhi,2008									
2.Electronic Measurements and instrumentation.	Oliver and Cage	ТМН, 2009									



ं कर्मस्															
OEEC-612A Principle of Communication Engineering															
			1	Prii L	icipie o	r Com		ation E		ering P			Credit	ta	
				<u> </u>			L)			<u>r</u> 0			<u>Creun</u> 3	.5	
		Sessio	nal Ma	-			0			U			50		
					ination	Marks							50		
Cours	P							underst	andino	the i	mporta	nce ar		ories of	
Object	_										-				
Objectives communication systems. The students will study the various analog communication techniques, generation, detection, transmission and reception										0 0					
Course 1. Gain knowledge about the fundamental concepts communication systems.															
·	Itcomes 2. Analyse AM, SSB, FM and PM transmission and reception circuits.														
								e and fi	requen	cy mod	ulated	system	s and de	esign of	
PAM, PWM and PPM systems.4. Acquire knowledge about the basic concepts of digital modulation a															
										ion and	demod	lulation			
techniques.											1				
	Mapping of course outcomes with program outcomes										0013	0001			
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	
CO1	3	2	2	2	2	2	0	1	0	2	1	2	3	3	
CO2	3	3	3	3	2	2	1	1	2	2	1	2	3	3	
CO3	1	1	1	0	1	2	0	1	1	1	3	2	3	3	
CO4	2	1	1	2	0	2	0	1	1	0	1	2	3	3	
					ι	J nit-I							1	12 hrs	
Introd	uctio	n: Co	mmunic	ation,	inform	ation,	messa	age ai	nd sig	gnals,	electro	magne	tic sp	ectrum,	
classifi	icatior	n of sign	nals, pe	riodic a	and non	-period	lic sign	als, and	alog ar	nd digit	al sign	als, det	terminis	stic and	
					municat										
					on, expr			/I wave	e, mod	ulation	index,	freque	ency sp	ectrum,	
bandw	idth, p	ower co	ontents	of side	bands ar		er.							101	
		1	0			<u>nit-II</u>	.1	6.6		1	1	.1		12 hrs	
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													ivi gen	eration,	
varactor diode modulator. DSB-SC, SSB, their comparison and areas of applications.															
Dulas	mode	lation	Comm1:	na mac.		nit-III	theorem	m not	rol cor	nnlina	flot to	n	ling as	12 hrs	
														mpling	
rate, aliasing, basic idea about PAM, PWM and PPM and typical applications, reconstruction of message, pulse code modulation (PCM) block diagram of PCM system quantization															
pulse code modulation (PCM), block diagram of PCM system, quantization.															



<u>Unit-IV</u>								
Elements of digital communication: Block diagram of digital communication system, di								
representation of analog signals, advantages and disadvantages of digital communication system,								
Digital carrier modulation techniques: Introduction, amplitude shift keying (ASK), ASK spectrum								
ASK modulator, frequency shift keying (FSK), PSK.								
Digital carrier demodulation techniques	Coherent ASK detector,	non-coherent ASK detec	tor, non-					
coherent FSK detector, coherent FSK detector	ctor.		·					
RECO	MMENDED BOOKS							
Title	Author	Publisher						
1. Communication Systems (Analog and Sanjay Sharma S.K. Kataria & Sons								
Digital)								
2. Electronic Communication Systems	Kennedy	Tata McGraw Hill						
3. Electronic Communications	Roddy and Coolen	Prentice Hall of Indi	a					

 4. Principles of Communication Systems
 Taub and Schilling
 Tata McGraw Hill

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							OFFC	619P								
OEEC-612B Optical Electronics																
				L		Op		ectron	lics	Р			Credits			
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					xamina	tion N	Morka						50			
C									•1•	• •,	1 /1 1					
Cours			The main objective of this course is to familiarize with the basics of semiconductor optoelectronics and various optical devices i.e. optical sources, modulators, photo													
<u>Objec</u>	tives	-					-			-				· •		
				display	device	s. Stu	dents v	vill als	o study	the mo	odern o	ptoelect	ronics ir	itegratec		
		syst	ems.													
Course 1. Use principles of physics to analyze the fundamental concepts of various optoelectroni										lectronic						
Outcomes components.																
2. Describe the characteristics of Optoelectronic devices.																
3. Familiarize with tools and processes used in fabricating optoelectronic components.																
4.Utilize knowledge to Implement optoelectronic communication systems.																
Mapping of Course Outcomes with program outcomes																
	PO1	PO2	PO3	PO4	PO5	PO6	P07	P08	PO9	PO10	PO11	PO12	PSO1	PSO2		
CO1	2	2	3	3	2	1	2	1	0	0	2	2	2	3		
CO2	3	3	3	3	2	2	0	1	2	1	0	1	2	3		
CO3	3	3	2	2	3	2	1	1	2	0	3	3	2	2		
CO4	3	3	3	3	2	2	2	1	2	0	3	3	2	2		
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													c optical			
												lemental	and co	mpound		
semico	onducto	or, elec	tronic	propert				esses ir	n semic	onducto	ors.		1			
<u> </u>						Unit-			<u> </u>				l .	14 hrs		
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modul		cicciio	-optic	Switch	and m	Juulai		I IIIOu	ulators	, 1012.101	mouu	lators, e	iecuo-au	sorption		
mouui	at01				1	Unit-I	ТТ							14 hrs		
Photo	detect	ors: P	rinciple	ofont				or perf	ormand	ce paran	neters	thermal	detectors			
	s, sola		pic	or opt			,	- P e 11		Paran				, p.10101		
			Jumine	scence.	photo	lumin	escence	e, cath	ode lui	minesce	ence, c	athode	ray tube	, electro		
-	•				-								•	ss, LCD		

Display devices: Luminescence, photoluminescence, cathode luminescence, cathode ray tube, electro luminescence, injection luminescence and light emitting diodes, plasma displays, display brightness, LCD, numeric displays.

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<u>Unit-IV</u>										
Optoelectronic integrated circuits: Introduction, hybrid and monolithic integration, application of										
optoelectronic integrated circuits, integrated transmitters and receivers, guided wave devices.										
RECOMM	ENDED BOOKs									
Title	Author	Publisher								
1. Semiconductor Optoelectronic Devices	Pallab Bhattacharya	Pearson Education Inc								
2. Photonics - Optical Electronics in Modern Communications	A. Yariv and P. Yeh,	Oxford University Press								
3. Opto Electronics – As Introduction to	Jasprit Singh	McGraw-Hill								
materials and devices		International								
4. Opto Electronics – An Introduction	J. Wilson and J. Haukes	Prentice Hall, 1995								



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outed	<u> </u>	2. 3. 4.	Perfor Evalua Utiliza	rm mat ate, ana e progr	alyze a ammin	cal moond plot nd plot ng skills Outcon	results to enh	ance le	arning		rforma	nce in o	enginee	ering.
	PO1	PO2	PO3	PO4	PO5	PO6	P07	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	3	3	3	2	3	1	1	1	2	1	2	3	2	2
CO2	2	3	3	3	3	2	1	1	2	1	1	2	2	3
CO3	3	3	3	3	3	0	0	1	3	2	2	3	1	2
CO4	3	2	2	3	3	1	0	1	3	2	2	3	3	2
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					<u> </u>	J nit-III								12 hrs
findin fitting	g eigen	values olation	& eige , data a	envecto malysis	ors, mars and st	ta ana trix fact atistics stics.	torizati	on, pol	ynomia	al curve	e fitting	g, least	squares	s curve
						J nit-IV								12 hrs
contro	l, zoon plots.	n-in and		-out, n	-	s, style ng plot	-			0				
							Au	thor				Publi	sher	
	<i>J</i> [v][v]]	Titl	L											
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1. Get 2. MA 3. MA in E	tting St	arted w Progra and Its ring	vith MA mming Applio	5	Y. Ra		Singh, Bansal	l	Chaudh	uri P P	PHI Pearson	Univers Educat ublicati	tion Inc	



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<u>Object</u>	ives							e shapi	U			0		
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		ע ידן						with p			mes			
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CO1	2	3	3	3	2	0	0	1	2	1	1	1	2	2
CO2	3	3	3	3	2	2	0	1	0	2	1	1	3	2
CO3	2	1	1	2	1	0	0	1	2	1	0	0	2	3
CO4	3	3	3	3	3	2	1	1	0	2	1	1	2	3
					U	nit-I							1	12 Hrs
Linear ramp a attenua Non-li	nd exp tors, R near v	onentia L and I vave sl	l inputs RLC ci naping	s, high j rcuits a : Diode	pass RO and the e clipp	C circui ir respo ers, tra	it as dif onse for ansistor	ferentia r step ir r clippe	ator and nput, ri ers, clij	d low panging constraints of the provided set	ass RC circuit. at two	circuit indepe	as inte	grator, levels,
emitter														
clampi									ing cir	cuit th	eorem,	praction	cal cla	mping
circuits	s, effec	t of dio	de cha	racteris		*	ing vol	tage.						
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Switch of satu saturat	ration													
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			-			nit-III							1	12 Hrs
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couple	d, and	emitter	couple	d mono	ostable	multiv	ibrator	, trigge	ring of	monos	table n	nultivib	rator, a	astable
-			-					table m	-					



<u>Unit-IV</u>

12 Hrs

Time base generators: General features of a time base signal, methods of generating time base waveform, Miller and Bootstrap time base generators – basic principles, transistor Miller time base generator, transistor Bootstrap time base generator, current time base generators, methods of linearity improvements.

Blocking oscillator circuits: Triggered transistor blocking oscillator, an astable transistor blocking oscillator, applications of blocking oscillators.

RECOMM	ENDED BOOKS	
Title	Author	Publisher
 Pulse, Digital and Switching Waveforms 3rd Edition, 2008. 	Millman and Taub	Tata McGraw-Hill
2.Microelectronic Circuits, 7th Edition 2014	Sedra and Smith	Oxford University Press
3. Pulse and Digital Circuits, 2006	Motheki S. Prakash Rao	Tata McGraw-Hill
4. Fundamental of Microelectronics, 2nd Edition 2009	B.Razavi	John-Wiley



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		l	Mappir	ng of C	ourse	Outcon	nes wit	h prog	ram oi	itcome	S			
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CO1	3	3	2	3	2	2	2	1	3	2	1	2	2	1
CO2	2	2	2	2	1	0	1	1	3	2	1	2	2	2
CO3	3	3	1	1	0	0	3	1	3	2	1	2	1	1
CO4	2	2	1	2	1	0	1	1	3	2	1	2	2	2
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Unit-IV

12 hrs

Micro system packaging and applications of MEMS: Micro system packaging, general considerations, the three levels of microsystems packaging, die level, device level and system level, essential packaging technologies, die preparation, surface bonding wire bonding and sealing, three-dimensional packaging, assembly of microsystems, selection of packaging materials.

The MEMS switch and its design consideration: The MEM resonator and its design considerations, micromachining-enhanced planar microwave passive elements.

RECON	AMENDED BOOKS	
Title	Author	Publisher
1. MEMS and Microsystems Design and Manufacture	Tai-Ran Hsu	Tata McGraw Hill
2. Fundamentals of Micro fabrication	Mark Madou	CRC Press
3. Micro sensors: Principles and Applications	J. W. Gardner	John Willey ,2009
4. Semiconductor Sensors	S. M. Sze	Tata McGraw Hill
5. An Introduction to Microelectromechanical Systems Engineering	Nadim Maluf and Kirt Williams	Artech, 2 nd Edition, 2004
6. Introduction to Microelectromechanical Microwave Systems	Hector J. De Los Santos	Artech, 2 nd Edition, 2004

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CO2	1	0	0	0	2	0	0	1	1	0	2	2	2	2
CO3	3	2	0	0	2	2	0	1	1	0	1	2	2	2
CO4	0	3	0	3	0	2	0	1	0	0	2	2	3	3
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Source coding, image and video: Image and video formats - GIF, TIFF, SIF, CIF, QCIF, image compression: READ, JPEG, video compression: principles-I, B, P frames, motion estimation, motion compensation, H.261, MPEG standard.

<u>Unit-III</u>	12 hrs.
Codes for error detection and correction: Parity check coding, linear block codes	, error detecting and
correcting capabilities, generator and parity check matrices, standard array and synd	lrome decoding.
Block codes: Definitions and principles: Hamming weight, Hamming distance,	minimum distance
decoding - single parity codes, hamming codes, repetition codes - linear block co	odes, cyclic codes -
syndrome calculation, encoder and decoder – CRC.	-
Unit-IV	12 hrs.

12 hrs.

Convolution codes: Code tree, trellis, state diagram, structural properties, encoding – decoding: sequential search and Viterbi algorithm - principle of turbo coding, soft-decision decoding, and Viterbi decoding algorithm.

Advanced coding techniques and cryptography: BCH codes, trellis coded modulation, introduction to cryptography, overview of encryption techniques, symmetric cryptography, DES, IDEA, asymmetric algorithms, RSA algorithm.

RECOM	MENDED BOOKS	
Title	Author	Publisher
1. Information Theory, Coding and Cryptography,	Ranjan Bose	Tata McGraw Hill
2. Applied Coding and Information Theory for Engineers	Richard B. Wells	Pearson
3. Coding and Information Theory,	.R. W. Hamming	Prentice Hall, 2 nd edition,
4. Information Theory and Reliable Communication,	R. G. Gallager,	Wiley
5. The Theory of Information and Coding.	R.J. McEliece	Addison – Wesley
6. Introduction to information Theory	M. Mansuripur,	Prentice Hall
7. Principles of communication	Taub & Schilling	McGraw Hill
8. Elements of Information Theory	Thomas Cover & Joy Thomas	John Wiley & Sons

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CO2	3	3	3	3	3	2	2	1	3	2	1	3	3	2
CO3	3	3	3	3	3	2	0	1	3	2	1	3	3	2
CO4	3	3	3	3	3	2	0	1	3	2	1	3	3	2

List of Experiments (Hardware):

PART-A

- 1. To measure the modulation index of AM signal using the sine wave method and trapezoidal
- 2. method.
- 3. To setup the circuit of AM modulator using transistor.
- 4. To setup the circuit of envelop detector for AM demodulation.
- 5. To study the DSB/ SC AM signal and its demodulation using product detector circuit.
- 6. To study the generation and detection of FM signals.
- 7. To study the AM transmitter circuit and observe the waveforms at test points.
- 8. To study the FM transmitter circuit and observe the waveforms at test points.
- 9. To study the AM receiver circuit and observe the waveforms at test points.
- 10. To study the sampling process and time division multiplexing.
- 11. To study the pulse amplitude modulation and demodulation circuits.
- 12. To study the pulse width modulation and demodulation circuits.
- 13. To study the pulse code modulation and demodulation circuits.

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Software (using MULTISIM)

- 1. To study the spectrum of pulses using spectrum analyzer.
- 2. To measure the modulation index of AM signal using the sine wave method and trapezoidal method.
- 3. To observe the amplitude spectrum and measure the bandwidth of AM signal.
- 4. To setup the circuit of AM modulator using transistor.
- 5. To setup the circuit of envelop detector for AM demodulation.
- 6. To setup the circuit of DSB/SC AM and DSB-FC AM using product modulator/multiplier.
- 7. To study the FM wave generated from FM source in MULTISIM and measure the modulation index by approximate method.
- 8. To observe the amplitude spectrum and measure the bandwidth of FM signal.
- 9. To generate FM signal using voltage-controlled oscillator on MULTISIM and observe the waveforms on CRO.
- 10. To generate pulse amplitude modulation (PAM) signal and observe its waveform.
- 11. To generate PWM signal using 555 timer IC and observe its waveform.
- 12. To generate PPM signal and observe its waveform.

PART-B

Hardware

- 1. To study time division multiplexing system.
- 2. to study pulse code modulation and demodulation.
- 3. To study delta modulation and demodulation and observe effect of slope overload.
- 4. To study pulse data coding techniques for various formats.
- 5. To study amplitude shift keying modulator and demodulator.
- 6. To study frequency shift keying modulator and demodulator.
- 7. To study phase shift keying modulator and demodulator.

Software

- 1. To generate BASK signal and observe the frequency spectrum on MULTISIM software.
- 2. To generate BPSK signal and observe the frequency spectrum on MULTISIM software.
- 3. To generate BFSK signal and observe the frequency spectrum on MULTISIM software.
- 4. To setup the model for BPSK baseband modulation for scatter plot to observe the constellation on MATLAB/SIMULINK software.
- 5. To setup the model for QPSK baseband modulation for scatter plot on to observe the constellation on MATLAB/SIMULINK software.
- 6. To setup the model for BFSK baseband modulation for scatter plot on to observe the constellation on MATLAB/SIMULINK software.
- 7. To setup the BPSK model with AWGN channel and perform error rate calculation/BER plot on MATLAB/SIMULINK software.
- 8. To setup the QPSK model with AWGN channel and perform error rate calculation/BER plot on MATLAB/SIMULINK software.
- 9. To setup the BFSK model with AWGN channel and perform error rate calculation/BER plot on MATLAB/SIMULINK software.

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Wave generator: Square wave generator, triangular wave generator, saw tooth wave generator and voltage-controlled oscillator, comparator, zero crossing detector, Schmitt trigger, window detector, V to F and F to V converters, A to D and D to A converters, peak detector.

Unit-IV12 hrsSpecialized IC applications: IC 555, pin configuration, block diagram, application of 555 as monostableand astable multivibrator, operating principles & applications of 565PLL.Voltage regulators: Fixed voltage regulators, adjustable voltage regulators, switching regulators.

RECON	AMENDED BOOKS	
Title	Author	Publisher
1.Op Amps & Linear Integrated circuits	Ramakant Gayakwad	Pearson Education
2. Fundamental of Microelectronics	B Razavi	Wiley India
3. Linear Integrated Circuits	D. Roy Choudhary	New Age International
4. Design with Operational Amplifiers and Analog Integrated Circuits	Sergio Franco	Tata Mc-Graw Hill

Department of Electronics & Communication



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CO2	1	2	3	3	1	0	2	1	1	0	2	2	2	2
CO3	3	2	1	2	2	1	1	1	1	0	2	2	2	3
CO4	2	2	0	0	1	2	2	1	0	0	3	2	3	3
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THE TOP OF TOP OF THE TOP OF TO	RECOMMENDED BOOKS												
Title	Author	Publisher											
1.Wireless Communications	T.S Rappaport	Pearson Education, 2003.											
2.Principles of Mobile Communication	Gordon L. Stuber	Springer International Ltd., 2001.											
3.Wireless Communications	Andrea Goldsmith	Cambridge University Press, 2007											



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CO2	3	3	2	3	1	2	2	1	0	0	1	2	2	3
CO3	3	3	3	3	2	2	2	1	1	0	1	2	3	3
CO4	3	3	3	3	0	0	2	1	0	0	0	3	2	3
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periphe	eral inte		8253 pr										a progr controlle	
													r motor	



RECON	MMENDED BOOKS	
Title	Author	Publisher
1.Microprocessor Architecture- Programming & Applications with 8085/8080A	Ramesh S Gaonkar	5 th Edition, Penram International Publishing
2.Introduction of Microprocessors & Microcomputers	Ram B	4 th Edition, Dhanpat Rai Publisher (P) Ltd.
3.Microprocessor Interfacing Technique	Rodnay Zaks and Austin Lesea	1 st Indian Edition, BPB Publication
4.An introduction to Intel family of Microprocessors	James L Antonakes	3 rd Edition, Pearson Education
5.Microprocessor Principles and Applications	Charles M Gilmore	2 nd Edition, McGraw Hill

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CO2	3	2	2	1	0	1	1	1	1	0	3	2	1	3
CO3	3	2	2	1	1	0	0	1	0	0	1	2	2	3
CO4	3	2	2	2	3	3	2	1	1	0	3	3	3	3
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Mask	k gene	ration.												
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Chemical vapor deposition techniques (CVD) : CVD techniques for deposition of polysilicon, silicon dioxide, silicon nitride and metal films, epitaxial growth of silicon: modeling and technology												d techno	ology	
dioxi														12hrs
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RECOMMENDED BOOKS												
Title	Author	Publisher										
1. The Science and Engineering of	1	Oxford University Press, 2012										
Microelectronic Fabrication	Campbell											
2. VLSI Technology 2 nd edition	Sze	McGraw-Hill Book Company, New Delhi, 1988										
3. VLSI Fabrication Principles	Sorab K. Gandhi	John Wiley, 1994										



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		E	nd Sem	ester E	xamin	ation N	Aarks						50	
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CO2	2	2	2	2	1	2	1	1	3	0	1	2	1	3
CO3	2	2	2	1	2	3	3	1	2	0	1	2	2	3
CO4	2	2	2	1	1	2	2	1	1	0	0	0	1	3
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RECOMM	ENDED BOOKS	
Title	Author	Publisher
1. Encyclopedia of Nanotechnology	Hari Singh Nalwa	Springer Inc.
2. Springer Handbook of Nanotechnology	Bharat Bhusan	Springer Inc.
3. Introduction to Nanotechnology	Poole Jr., C.P., Owens, F.J	Wiley Inc.
4. A Textbook of Nanoscience and Nanotechnology	B S Murthy	Springer Inc.



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					B	Biomed	dical El	ectron	nics					-
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			analy	-	liucityii	ig pin	licipic (uo-pny	siologi	cai sig		asurem	cint and
3. Conceptualize underlying technology with regard to constructional and functional														
details of biomedical equipment.														
		4.						g tech	nniques	in ex	tractin	g info	rmatio	n about
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					of Cour									
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	3	2	2	2	2	1	1	1	0	0	2	3	3	3
CO2	2	3	3	3	3	1	2	1	2	0	2	3	3	2
CO3	2	0	0	3	3	3	3	1	1	0	1	3	3	2
CO4	3	2	2	2	3	0	1	1	2	0	1	3	3	3
	I					Unit-	I							10 hrs
Biome	edical	instrur	nentati	on: Ma	an-instru	ument	system	, physi	ologica	l syster	ns of h	uman,	transdu	cers for
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action	poten	tials, b	ioelectr	ic pote	ential, e	electro	de theo	ory, bi	oelectri	c poter	ntial el	ectrode	s, bioc	hemical
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			_	_		Unit-l								14 hrs
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meters	s, spiro	meny a	ina pun	nonary		Unit-l		ms.						12 hrs
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	<u>Unit-IV</u>	12 hrs										
Biotelemetry: Physiological parameter	ers adaptable to biotelemetry, com	ponents of biotelemetry system,										
implantable units, applications in patient care and monitoring, wireless telemetry, single channel telemetry												
system, multi-channel wireless telemetry system, multi-patient telemetry, implantable telemetry system,												
analog physiological signal transmission over telephone lines and telemedicine.												
RECOMMENDED BOOKS												
Title	Author	Publisher										
1. Biomedical Instrumentation	Leslie Cromwell, Fred J. Weibell	Pearson Prentice Hall2006										
and Measurements	and Erich A. Pfeiffer											
2. Introduction to Biomedical	Joseph J. Carr and John M.	Pearson Education India, 2001										
Equipment Technology	Brown											
3. Handbook of Biomedical	R. S. Khandpur	Tata-McGraw Hill Education,										
Instrumentation		2003										

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					Co	ontrol S	ystem l	Engine	ering					
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		Sessi	onal M	arks									50	
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CO1	3	2	2	3	0	0	0	1	2	0	1	2	3	3
CO2	3	1	1	1	0	0	0	1	1	0	0	1	3	2
CO3	3	3	2	2	0	0	0	1	0	0	0	1	3	2
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and lead-lag compensation networks.

Department of Electronics & Communication



Unit-IV10 hrsState variable analysis: State space representation of continuous time systems, state equations, transferfunction from state variable representation, solution of state equations, controllability and observability,state space representation of discrete time systems.

RECOMMENDED BOOKS												
Title	Author	Publisher										
1. Modern Control Engineering	Ogata K	Prentice Hall, 5th Edition 2010										
2. Automatic Control Systems	Kuo BC	Prentice Hall, 9th Edition 2014										
3. Modern Control Systems Engineering,	Nagrath I J and Gopal M	New age international, 3rd Edition, 2014.										
4. Linear Control System	B S Manke	Khanna Publishers, 12th edition										

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		uı	nderstan	ding th	ne desig	gn of 1	heat sir	nk, and	l impor	tance	of grou	nding.	It will	impart
		pı	actical l	knowle	dge of e	electro	nic syst	tem de	sign.					
Cours	se	1.	Explain	n and ic	lentify t	he dev	vices wł	nich ca	n be use	ed in ap	plicatio	ons like	power	supply,
Outco	omes		amplifi	ers etc.										
		2.	Design	and de	evelop li	inear a	nd vari	able po	ower su	pply.				
		3.	Addres	s desig	n challe	enges f	for amp	lifiers	using tr	ansisto	or and o	p-amps		
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CO1	2	2	2	2	0	0	0	1	0	0	1	1	1	3
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CO2	2	3	3	3	2	2	1	1	2	0	2	3	3	2
CO3	3	3	3	2	0	2	3	1	0	0	3	3	3	3
CO4	3	2	1	2	0	0	0	1	1	0	1	2	2	2
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circuit	t protec	tion, f	oldback	protec	tion cire	cuit, I	C volta	ge regu	lators,	fixed v	voltage	regulat	ors, ad	justable
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and SI	MPS.													
						<u>it-III</u>								12 hrs
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111 UIII		omigu	rations.		TIm	nit-IV								10 hrs
					UI	111-1 V								10 11/5



Cooling and grounding of electronic system: Heat transfer approach to thermal management, mechanisms for cooling, basic thermal calculations, heat sink selection, and heat sink design. Safety grounds, signal grounds, high frequency ground methods, low frequency grounding methods, chassis grounding.

RECOM	RECOMMENDED BOOKS												
Title	Author	Publisher											
1. Electronic Instrument Design, 1st edition	Kim R. Fowler	Oxford University Press.											
2. Digital Design Principles& Practices, 3rd edition	John F. Wakerly	Prentice Hall											
3. Practical Analog Design Techniques	Adolofo Garcia and Wes Freeman	Seminar Materials											
4.The Art of Electronics	Paul Horowitz	Cambridge University Press, 2011											

Department of Electronics & Communication



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		Er	nd Sem	ester H	Examina	ation]	Marks						50					
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CO2	3	1	1	1	1	0	0	1	1	1	1	0	3	2				
CO3	3	3	2	2	1	0	0	1	0	0	1	0	3	2				
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					Uni	it-III								12 hrs				
versus	s phase	angle	plot, bo	de plo	tion and ts, Nyqu								0	0				
and le	ad-lag	comper	nsation	networ	rks.													



12 hrs
tions, transfer
observability,

RECOMM	RECOMMENDED BOOKS												
Title	Author	Publisher											
1. Modern Control Engineering	Ogata K	Prentice Hall, 5th Edition 2010											
2. Automatic Control Systems	Kuo BC	Prentice Hall, 9th Edition 2014											
3. Modern Control Systems Engineering,	Nagrath I J and Gopal M	New age international, 3rd Edition, 2014.											
4. Linear Control System	B S Manke	Khanna Publishers, 12th edition											



			T		•		PEEC-			1 NT.	4			
			Te	elecom L		cation S	witch	ing Sys T	stems a	and Ne	tworks		Credits	
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CO2	3	3	3	3	1	0	0	1	1	0	1	2	2	3
CO3	3	2	0	0	2	2	2	1	0	0	2	3	2	3
CO4	3	3	3	3	0	1	1	1	1	0	2	2	2	1
CO5	3	2	0	0	1	3	3	1	0	0	3	3	2	2
					l	Unit-I							•	12 hr
Teleo	comm	inicat	ions tr	ansmi	ission	Basic s	witchi	ng syst	tem, sin	nple te	le-phone	comm	unicatio	on.
Swite	ching	systen	ns: Str	onger	switch	ning syst	ems, c	cross b	ar swit	tching,	electron	ic swit	ching –	space
divisi	ion sw	vitchin	g, tim	e divi	sion s	witching	g –tim	e divi	sion s	pace sv	vitching.	time	division	n tim
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				نما مغيبي										

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माय कार्या										
	<u>Unit-IV</u>	12 hrs								
Telephone networks and sign	alling: Introduction, subsci	riber loops systems, switching hierarchy,								
transmission and numbering pla	ns, common channel signall	ing principles, CCITT signalling systems.								
	RECOMMENDED BOOKS									
Title	Author	Publisher								
1.Telecommunications	Flood J E	Pearson education Asia, (2001).								
Switching, Traffic and										
Networks										
2.Telecommunication	Viswanathan T	PHI, India, (2003).								
Switching Systems and										
Networks										
3.Signaling in	Bosse J G van, Bosse	Wiley, John & Sons, (1997).								
Telecommunication Networks	John G									
4. Switching in IP Networks:	Bruce S. Davie, Paul	Elsevier Science & Technology Books,								
IP Switching, Tag Switching,	Doolan, Yakov Rekhtor	(1998)								
and Related Technologies										
5. Switching and Traffic	Joseph Yu Hui	Kluwer Academic Publishers, (1990).								
Theory for Integrated										
Broadband Networks										

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							EEC-62									
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			End Se	mester	Exam	ination	n Mark	s				50				
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Objec	tives		0						0	ing of va	-					
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CO2	3	3	3	3	3	2	2	1	0	0	1	2	3	2		
CO3	3	2	1	2	3	1	1	1	1	0	2	2	1	3		
CO4	3	2	2	3	3	1	2	1	1	0	1	1	1	3		
CO5	3	2	3	3	3	0	0	1	0	0	1	2	2	2		
			•			Unit-I								12 hrs		
Introd	luction	n: Ciro	cuit desi	gn, MC				d mode	el par	ameters,	interco	nnects				
						Unit-II								12 hrs		
										ng theory			fects, p	arasitic		
eleme	nts, M	JSFE	circuit	models		-		arrier ar	nd she	ort chann	el effec	ets.		101		
MOG		4.0				Unit-II			ia V				I annual	12 hrs		
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unnon	in dop	Ju sub	strate.		1	Unit-IV	7							12 hrs		
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1. Fun	damen	tal of]	Modern	VLSI I	Design	Yuan T			ing	Cambric				2011		
			ntegrated		<u> </u>	Sung-N				Tata Mc	0		,			
3. Ope	eration	and M	odelling	g of the	MOS	Yannis	Tsivid	lis		Oxford	Univers	ity Pre	ss			
Transi	stor		-													

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Sarbjeet Singh

Dilip Kumar J.S. Ubhi



							PCEC	C-623								
					Lir	near In	tegrat	ed Cir	cuit La	ab						
				L			Т		Р			Cre	edits			
			0 0 2 1													
Cours	se	This 1	ab incl	udes co	omplete	e analy	tical as	s well a	s desig	gning ci	rcuits u	sing op	o-amp. It	t includes		
Objec	ctives	design	n of va	rious a	applicat	tions u	sing o	p-amp	as inte	egrator,	differe	ntiator,	log, an	tilog and		
		wave	genera	tion cir	cuits.			_								
Cours	se	1. Exa	amine t	he perf	forman	ce of o	p-amp	in inve	rting a	s well a	is in nor	n-invert	ting mod	les.		
Outco	omes	2. Des	sign of	variou	s applic	cations	using	op-am	5.							
		3. Des	sign dif	ferent	wave g	enerati	ng circ	cuits us	ing op	-amp.						
			U		ner and		U		0 1	1						
			M	apping	g of Co	urse O	utcom	nes wit	h prog	ram ou	itcomes	5				
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2		
CO1	3	3	3	3	2	0	0	1	3	2	1	2	3	3		
CO2	3	3	3	3	3	2	2	1	3	2	1	2	3	2		
CO3	3	3	3	3	3	2	2	1	3	2	1	2	3	3		
CO4	3	2	2	2	3	2	2	1	3	2	1	2	3	2		

List of Experiments:

- 1. Design and analyze RC-circuit as low pass and high pass using active filters.
- 2. Design and analyze RC-circuit as low pass and high pass using passive filters.
- 3. Verify the differential amplifier configurations.
- 4. Measure the performance parameters of an op-amp.
- 5. Application of op-amp as inverting and non-inverting amplifier.
- 6. Verify the frequency response of an op-amp.
- 7. Use the op-amp as summing, scaling & averaging amplifier.
- 8. Use the op-amp as instrumentation amplifier.
- 9. Design and analyze differentiator and integrator using op-amp.
- 10. Application of op-amp as log and antilog amplifier.
- 11. Application of op-amp as saw tooth wave generator.
- 12. Application of op-amp as Schmitt Trigger.
- 13. Design and analyze multivibrator circuits using 555.
- 14. To examine the operation of a PLL and to determine the free running frequency, the capture range and the lock in range of PLL.

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							PCEC	C-624								
					MA	TLA	B Prog	gramn	ning La	ab						
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Cour	se	The	aim of	f this	course	is to	introd	uce th	e stude	ents to	the MA	TLAB	program	nming		
Obje	ctives	lang	uage fo	or num	erical o	compu	tations	and it	s appli	cation i	n engine	eering a	nd tech	nology		
Cour	se	1. U	Jnders	tand ba	sic con	nmano	ds, mai	nage co	ontents	and de	velop pr	ograms	in MA	ΓLAB.		
Outc	omes															
		3. Evaluate, analyze and plot results.														
		4. U	Jtilize	progra	mming	g skills	to enh	nance l	earning	g and pe	erformai	nce in e	ngineeri	ing.		
		N	Iappi r	ng of C	Course	Outco	omes v	vith Pi	rogran	1 Outco	omes					
	PO1	PO2	PO3	PO4	PO5	PO6	P07	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2		
CO1	2	3	3	3	3	1	0	1	3	2	1	2	2	3		
CO2	2	3	3	3	3	1	2	1	3	2	1	3	2	3		
CO3	2	3	3	3	3	3	0	1	3	2	1	2	2	3		
CO4	2	1	3	3	3	3	2	1	3	2	1	3	3	3		

List of Experiments:

- 1. Familiarizing with basic elements of MATLAB's desktop, MATLAB windows, MATLAB editor input-output, file types, general commands, variables, numbers, working with arrays of numbers and array arithmetic operations.
- 2. Write a MATLAB program to display a matrix. Also find its length, width, divergence, transpose and inverse.
- 3. Write a MATLAB program to calculate matrix addition, multiplication, division and eigen value calculations.
- 4. To study basic 2-D plots, style options, labels, title, legend, and other text objects, axis control, modifying plots specialized 2-D plots, layout of multiple plots, mesh and surface plots, 3-D plots.
- 5. Write a script file to calculate addition, subtraction, multiplication, division, square, square root, cube and cube roots of integer numbers.
- 6. Familiarizing with control flow structures branching statements, loops and their operators.
- 7. Write a script file to find the largest of three numbers (use if-elseif-else).
- 8. Generate a 10-by-10 matrix A = [akl], where akl = sin(k)cos(l). (use for loop)
- 9. The number π is divided by 2. The resulting quotient is divided by 2 again. This process is continued till the current quotient is less than or equal to 0.01. Write a script file to find the largest quotient that is greater than 0.01? (use while).
- 10. Write a script file to generate 5 different magic squares.
- 11. Fibonacci numbers are computed according to the following relation:

12. $F_n = F_{n-1} + F_{n-2}$, with $F_0 = F_1 = 1$

- 13. Create a function for generating the Fibonacci numbers with user defined function as (function $f = Fib_1(n)$)
- 14. To study functions for numerical integration,
- 15. To study functions for differential and non-linear algebraic equations.
- 16. To study symbolic computation in MATLAB and evaluate symbolic expressions.

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MATLAB SIMULINK

- 1. To generate BASK signal and observe the frequency spectrum on MULTISIM software.
- 2. To generate BPSK signal and observe the frequency spectrum on MULTISIM software.
- 3. To generate BFSK signal and observe the frequency spectrum on MULTISIM software.
- 4. To setup the model for BPSK baseband modulation for scatter plot to observe the constellation on MATLAB/SIMULINK software.
- 5. To setup the model for QPSK baseband modulation for scatter plot on to observe the constellation on MATLAB/SIMULINK software.
- 6. To setup the model for BFSK baseband modulation for scatter plot on to observe the constellation on MATLAB/SIMULINK software.
- 7. To setup the BPSK model with AWGN channel and perform error rate calculation/BER plot on MATLAB/SIMULINK software.
- 8. To setup the QPSK model with AWGN channel and perform error rate calculation/BER plot on MATLAB/SIMULINK software.
- 9. To setup the BFSK model with AWGN channel and perform error rate calculation/BER plot on MATLAB/SIMULINK software.

Department of Electronics & Communication



							TPID	-621								
	Industrial Training (4 weeks)															
			I			ŗ	Г]	P			Credits	5			
			()			0	4	0			2 (S/US)			
Cours	se	The main objective of industrial training is to familiarized students with industrial working											orking			
Objec	ctives	environment and enhance their knowledge skills towards developing a holistic perspective														
		to un	to understand various practical issues and latest trends in the field. The students will be													
		able t	able to troubleshoot various engineering faults related to their respective fields. They will													
	be able to learn ethical management practices.															
Cours	se	After successful completion of industrial training, the students should be able to														
Outco																
		2: co	rrelate	the the	eoretic	al conc	cepts w	vith the	real-li	fe indus	strial en	vironme	nt.			
								nsform	ing the	emselve	s into	an optir	num bl	end of		
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	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2		
CO1	3	2	2	2	2	2	2	3	3	3	1	3	3	1		
CO2	3	2	3	3	3	3	3	2	2	3	1	3	3	1		
CO3	3	3	2	3	2	2	2	2	1	3	1	3	3	3		
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			The cond	-	multira	te sig	nal pro	cessing	g and s	ample 1	rate co	nversio	n will	also be		
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Outco	omes		2. Comp								gnais.					
			3. Under 4. Design							essing.						
			4. Desigi	l'ulgita	1 mers	using	stanuar	u teem	nques.							
			Ma	pping	of Cour	rse Ou	tcomes	s with	progra	m outc	omes					
	PO1	PO2		PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2		
CO1	3	3	3	2	1	0	0	1	0	0	1	1	2	3		
CO2	3	3	3	3	3	0	1	1	2	0	0	2	2	3		
CO3	3	3	3	3	2	1	1	1	1	0	1	2	1	3		
CO4	2	3	3	3	2	1	0	1	0	0	2	3	3	3		
					U	nit-I								10 hrs		
Intro	ductior	n: Ad	vantages	of digi			essing	over a	nalog si	gnal pro	ocessin	g and it	ts appli			
			digital si													
			ted comp													
of disc	crete-ti	me s	ystems, d	iscrete	time sy	stems	describ	bed by	differer	nce equa	ation, c	orrelati	on of c	liscrete		
time s	ignals.															
						<u>nit-II</u>								16 hr:		
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using	uecinia	uion	in time a			iit-III	luency	lechint	lues.					16 hr:		
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-	windo	ws.	IIR filte					-			-					



	Unit-IV		06 hrs
Multirate signal processing: Introduction	, interpolation and decimation.		
RECO	DMMENDED BOOKS		
Title	Author	Publisher	
1. Discrete Time Signal Processing, 3rd Edition 2014	Oppenheim A V & Sehafer R W	Prentice Hall	
 Digital Signal Processing, 4th Edition 2006 	Proakis J G & Manolakis D G	Pearson	
3. Signal & Systems, 2nd Edition 2009	Oppenheim A V, Willsky A S & Young I T	Wiley Eastern Ltd N. Delhi	
4. Digital Signal Processing, 4th Edition 2013	S.K Mitra	Tata Mc-Graw Hill	



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					Anter	nna an	d Wav	e Prop	agation	l				
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		Er	nd Sem	ester E	xamin	ation	Marks						50	
<u>Course</u> Object	_	ba wi	e aim c sic para ll also nospher	meters be dise	. Vario	ous ant The	ennas, wave p	arrays ropaga	and the tion wi	ir spec ll enab	ial feat le the	ures an	d appli	ication
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Outco		2.	Descri	ibe the	atmosp	oheric a	and terr	estrial	effects of	on radio	o wave	propag	ation.	
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	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	3	3	3	3	3	2	2	1	2	0	1	3	2	2
CO2	3	3	3	2	3	3	1	1	1	0	2	3	2	3
CO3	3	3	2	2	2	1	2	1	2	0	1	3	2	3
CO4	3	2	2	3	3	1	2	1	2	0	2	2	3	2

Basic antenna parameters: Radiation mechanism, radiation patterns, antenna beam area, antenna beam width, radiation intensity, gain, directive gain, power gain, directivity (D), antenna bandwidth, effective height, reciprocity theorem, self-impedance, mutual impedance, radiation resistance, front to back ratio, radiation power density.

Radiation principles: Retarded vector potential, isotropic radiators, near field and far field concept, radiation from a half wavelength dipole, power radiated by a current element and its radiation resistance.

Unit-II12 hrsWire radiators: Voltage and current distribution, asymptotic current distribution in dipole, analysis of
linear wire elements, Hertz dipole antenna, monopole radiators, resonant and non-resonant antennas.Special antennas: Aperture antennas, E & H -plane horn antennas, pyramidal horn, lens and reflector
antenna, frequency independent antennas, log periodic antenna, antenna measurements, microstrip
antennas & their advantages, antenna for receiving and transmitting TV signals e.g. Yagi-Uda and turnstile
antennas.

Unit-III12 hrsAntennas array: Introduction, linear uniform arrays of isotropic sources, principles of pattern
multiplication. broadside arrays, end fire arrays, array pattern synthesis, uniform array, binomial array,
Chebyshev arrays.

Department of Electronics & Communication

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Unit	·IV		12 hrs
Propagation of radio waves: Structure of ior	nospheric region, different	modes of propaga	tion: ground
waves, space waves, space wave propagation	over flat and curved ear	th, optical and rac	lio horizons,
surface waves and troposphere waves, wa	ve propagation in the i	onosphere, critica	l frequency,
maximum usable frequency (MUF), skip dist	ance, virtual height, radio	o noise of terrestria	al and extra-
terrestrial origin, effect of earth's curvature, d	uct propagation, troposph	ere scatter propaga	tion.
RECOM	MENDED BOOKS		
Title	Author	Publi	sher
1. Antennas	Kraus	Mc Graw Hill	
2. Antennas	Balanis	Mc Graw Hill	
3. Antenna and Wave Propagation	K D Parsad	Parkash Publi	cations
4. Electromagnetic Waves and Radiating	K. G Balmain, E	. C PHI	
Systems	Jordan		

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Outcomes						onic c									
	2. C	Gain	know	ledge	about	fabric	ation	proce	ss and	challe	enges.				
	3. D	Desci	ribe va	arious	VLSI	fabric	cation	tools	and te	chniqu	les.				
	4. P	Proce	ess inte	egratio	on for	NMO	S, CM	IOS a	nd bip	olar c	ircuit	s.			
				~		1			- U	ram o					
	P						PO6	PO7	PO8			PO11			
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CO2		3	1	3	2	3	0	3	1	0	0	2	0	2	3
СО3		3	2	2	1	0	0	0	1	0	2	3	0	3	3
CO4		3	2	2	1	0	0	0	1	1	2	3	0	1	2
					Unit-	·I		•		1					10 hrs
Introduction:	Cou	ırse	intro	ductio	n, m	odern	semi	condu	ictor	IC fa	abrica	tion i	ndust	rial/ac	ademic
landscape, clas	ssifica	tion,	, scalii	ng thio	ck filn	n, thin	film a	and hy	/brid i	ntegra	ted ci	rcuits,	crysta	ıl stru	ctures.
					Unit-										10 hrs
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infrastructure,														_	
Oxidation: S		-			0							,			
dioxide grow											nolog	ies in	VLS.	l and	ULSI,
characterizatio	on of o	ox1de	e films				k diele	ectrics	s for U	LSI.					141
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pattern transfe		· ·			-		·c ·	1.			cc :	• • •		111	cc
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stopping, elect		-		-			-			-					
Epitaxy and			-					-				-			-
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(VPE), liquid	phase	epita	axy (L				eam ep	pitaxy	(MBI	Ξ),					
T		1	1		Unit-l										14 hrs
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common wet e					-		0				•				
Metal film o	_			-		-		ng te	chniqu	ies, F	ailure	e mecl	nanisn	ns in,	, metal
interconnects a	and m	ulti-	level r	netalli	izatio	n schei	mes.								

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RECOMMENDED BOOKS												
Title	Author	Publisher										
1.The Science and Engineering of	Stephen A. Campbell	Oxford University Press										
Microelectronic Fabrication												
2. Fundamentals of Semiconductor	S. M. Sz	Wiley, 2003										
Fabrication												
3.Introduction to Microelectronic	Richard C Jaeger	Prentice Hall, 2002										
Fabrication												



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				3			0			0			3	
		Ses	sional	Marks	5								50	
		En	d Seme	ester E	xamin	ation N	Marks						50	
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Objec	tives	dev	ices a	nd cir	cuits	by usi	ing di	fferent	desig	n tech	nologie	s used	for d	esign o
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		inte	grated	system	ns.									
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CO2	3	3	3	3	3	2	0	1	2	2	3	0	2	3
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						waves,					tronics,	need of	f optoele	
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Sarbjeet Singh



Title	Author	Publisher
1. Semiconductor Optoelectronic Devices	Pallab Bhattacharya	Pearson Education Inc
2. Photonics - Optical Electronics in Modern Communications	A. Yariv and P. Yeh,	Oxford University Press
3.Opto Electronics – As Introduction to materials and devices	Jasprit Singh	McGraw-Hill International
4.Opto Electronics – An Introduction	J. Wilson and J. Haukes	Prentice Hall, 1995



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CO3	1	3	3	2	0	1	1	1	1	0	2	2	1	2
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12 hrs

Unit-IV Radar Systems: Radar transmitters, basic configurations: self-excited power oscillator, master oscillator power amplifier (MOPA), comparison of tubes for radar transmitters, modulators, pulse forming network, block diagram of radar receiver, mixers, duplexers, displays

Tracking and scanning: tracking with radar, sequential lobbing, conical scanning, block diagram and operation, simultaneous lobing or monopulse tracking radar, amplitude comparison monopulse radar, block diagram and description for one angular coordinate and two (angular azimuth and elevation) coordinates, phase comparison monopulse radar.

RECOMMENDED BOOKS											
Title	Author	Publisher									
1. Microwave and Radar Engineering	M Kulkarni	Umesh Publications, Delhi									
2. Foundation of Microwave Engg	R. E. Collin	Tata McGraw Hill									
3. Introduction to Radar Systems	Skolnik, M.	Tata McGraw-Hill, 2001									
4.Microwaves	K C Gupta	New Age International									
5.Elements of Electronic Navigation Systems	N. S. Nagaraja	Tata McGraw-Hill, 2000									
6. Introduction to Radar Engineering	Sen & Bhattachrya	PHI									



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-			n: Sign			present	tation, f	fixed a	nd float	ing-poi	nt repr	esentat	ions, cl	haracte		
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					U	nit-II								14 hr		
Comj	puter i	nstruc	tion set	t: Intro	ductior	i, opco	ode enc	oding,	addres	sing mo	odes, ir	nstructi	on typ	es, dat		
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Performance

	Unit-IV	14 hrs								
Memory organization: Introduction,	memory interleaving, charact	eristics of memory systems,								
main memory design, concept of hierarchical memory organization, cache memory: cache size vs										
block size, mapping functions, replacement algorithms, write policy, associative memory, virtual										
memory and memory management concepts.										
Peripheral devices and their ch	aracteristics: Input-output s	ubsystems, basic concepts								
programmed I/O, standard vs memor	y mapped I/O, I/O transfers - J	program controlled, interrupt								
driven and DMA, software interrupts	and exceptions.									
RE	COMMENDED BOOKS									
Title	Author	Publisher								
1. Computer Organization and	Carl Hamachar, Zvonco	5th Edition, McGraw-Hill,								
Embedded Systems	Vranesic and Safwat Zaky	2002								
2. Computer Organization and architecture – Designing for	William Stallings	6th Edition, Pearson, 2003								

Department of Electronics & Communication



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Outcomes electronics.														
Outcomes electronics. 2. Learn the characteristics of power semiconductor switches.														
 Learn the characteristics of power semiconductor switches. Analyze single phase and three phase power converter circuits and their applications. 														
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phase l	half wa	we cyc	lo-conv	erters,	output	voltage	e equati	on for	<u>a cycl</u> o	-conve	rter.			

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RECOMMENDED BOOKS												
Title	Author	Publisher										
1. Power Electronics-Circuits, Devices and Applications	M H Rashid	PHI, 2nd Edition (1998).										
2. Industrial Electronics	G K Mithal	Khanna Publishers, Delhi, 18th Edition (1998).										
3. Industrial Electronics	S N Biswas	Dhanpat Rai and Company, Delhi, 3rd Edition (2000).										
4. Power Electronics	P S Bhimbra,	Khanna Publishers, Delhi, 3rd Edition (2002).										
5. Power Electronics	M D Singh, Khanchandani K B	TMH, 6th reprint (2001).										



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CO2	3	3	2	1	1	1	2	1	1	0	3	0	0	3
CO3	3	3	3	3	2	2	2	1	1	0	3	0	3	3
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Unit-IV

12 hrs

Introduction to VHDL: Overview of digital design with VHDL, basic language elements, data objects, classes and data types, operators, overloading, logical operators, VHDL representation of digital design entity and architectural declarations, introduction to behavioural, dataflow and structural models, applications of VHDL to FPGA design.

RECOM	MENDED BOOKS	
Title	Author	Publisher
1. An Engineering Approach to Digital Design	Fletcher William, I	3 rd Indian reprint, PHI, (1994).
2. Digital Design	Morris Mano M	3 rd Edition, Pearson Education (2002).
3. VHDL-Analysis and Modeling of Digital Systems	Navabi Z	McGraw Hill.
4. Fundamentals of Logic Design	Charles H. Roth Jr	4 th Edition, Jaico Publishers (2002).
5. VHDL for Programmable Logic	Skahill Kevin	1 st Indian Reprint, Pearson Education (2004).
6. Verilog HDL: A Guide to Digital Design and Synthesis	Samir Palnitkar	2 nd Edition, Prentice Hall PTR

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CO2	3	3	2	1	2	0	0	1	2	2	2	3	2	3
CO3	3	3	3	2	2	1	1	1	1	0	1	3	2	3
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CO2	1	2	3	3	1	2	0	1	1	2	2	2	2	2
CO3	3	2	1	2	2	2	1	1	1	1	2	3	2	2
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RECOMMENDED BOOKS												
Title	Author	Publisher										
1.Wireless Communications	T.S Rappaport	Pearson Education, 2003.										
2.Principles of Mobile Communication	Gordon L. Stuber	Springer International Ltd., 2001.										
3.Wireless Communications	Andrea Goldsmith	Cambridge University Press, 2007										



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		digita	l time o	causal s	systems	s. Later	on, St	udents	will le	arn hov	w to de	sign Lo	ow Pas	s, High			
		Pass,	Band P	ass and	FIR fi	lter wit	h the h	elp of I	Matlab.								
Cour	se							-									
Course1. Design of Discrete time causal system.Outcomes2. Verify various mathematical operations with the help of MATLAB.																	
0410		3. Design of digital FIR and IIR filters using different approaches and their associated															
		structures.															
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CO2	3	3	3	3	3	0	1	1	3	2	1	1	2	2			
CO3	2	3	3	3	2	1	0	1	3	2	1	2	2	3			
CO4	3	3	3	3	2	1	1	1	3	2	1	2	1	2			
				1							1		1				

List of Experiments:

- 1. Write a program in Matlab to generate standard sequences.
- 2. Write a program in Matlab to compute power density spectrum of a sequence.
- 3. To write a Matlab program to verify correlation and autocorrelation.
- 4. Write a program in Matlab to verify linear convolution.
- 5. Write a program in Matlab to verify the circular convolution.
- **6.** To write a Matlab programs for pole-zero plot, amplitude, phase response and impulse response from the given transfer function of a discrete-time causal system.
- 7. Write a program in Matlab to find frequency response of different types of analog filters.
- 8. Write a program in Matlab to design FIR filter (LP/HP) through Rectangular Window technique.
- 9. Write a program in Matlab to design FIR filter (LP/HP) through Triangular Window technique.
- 10. Write a program in Matlab to design FIR filter (LP/HP) through Kaiser Window technique.
- **11.** Write a program in Matlab to find the FFT.
- **12.** Implementation of low-pass, high pass and band-pass filter on some chosen signal.

Department of Electronics & Communication



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Cour	se	This la	ab aims	to get	familia	rize the	e studen	ts abou	t the va	rious c	ommur	nication	antenr	as used
Obje	ctives	in mic	in microwave range. It includes their design, gain, directivity, VSWR and various											
		charac	teristic	s. Furt	her in	this lal	studer	nts wil	l attain	the kn	owledg	ge abou	it opera	ation of
		variou	s Plane	-Tee.									•	
Cour	se	1. Eva	luate g	ain, dir	ectivity	and o	ther ant	enna p	aramet	ers.				
Outco		2. Measure the impedance matching characteristics of antennas.												
		3. Analyze the performance waveguide components.												
						,	guiue c	ompon	ents.					
		4. Des	ign an	-			RF and	-		requenc	y range	e.		
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List of Experiments:

- 1. To understand the working of the Motorized antenna trainer.
- 2. To investigate the properties of a Yagi antenna comprising a dipole and a parasitic element.
- 3. To know the form of a Yagi antenna and examine multi element antenna. To see how gain and directivity increase as element numbers increase.
- 4. To investigate the gain, and directivity of the log Periodic antenna over a wide frequency range.
- 5. To plot the radiation pattern of a directional antenna.
- 6. To measure antenna parameters (directivity, gain, beam width, half power beam width, front to back ratio) with polar plot of dipole antenna.
- 7. To measure antenna parameters of monopole antenna.
- 8. To measure antenna parameters of patch array antenna.
- 9. Identification of different waveguide components.
- 10. Study of the characteristics of klystron tube and to determine its electronic tuning range.
- 11. By use of slotted waveguide, to observe how the load impedance affects the VSWR.
- 12. To measure the VSWR of the antenna.
- 13. To determine the frequency & wavelength in a rectangular waveguide working on TE_{10} mode.
- 14. To be familiar with the operation of directional coupler.
- 15. To determine the standing wave-ratio and reflection coefficient.
- 16. To be familiar with the operation of E Plane-Tee.
- 17. To be familiar with the operation of H Plane-Tee.
- 18. To be familiar with the operation of Magic-Tee.
- 19. Measurement of the gain of horn antenna using Method of the two antennas.
- 20. To measure antenna parameters of horn (E, H, Pyramidal) & open waveguide antenna.
- 21. To measure antenna parameters of conical horn antenna.
- 22. To setup a satellite communication link.



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		projec	project work shall consist of substantial multidisciplinary component													
Cours	se	Upon completion of the project, the students will be able to														
Outco	omes	1. Select a suitable project making use of the technical and engineering knowledge gained														
		from previous courses with the awareness of impact of technology on the society and														
	their ethical responsibilities.															
		2. C	ollect a	nd diss	eminat	te infor	matior	n relate	d to sel	ected p	roject.					
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CO2	1	3	2	2	3	0	0	3	3	2	2	0	1	2		
CO3	3	3	3	3	3	2	3	3	3	3	3	0	2	3		
CO4	2	1	0	2	3	3	0	1	3	3	2	3	3	2		
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CO2	3	3	3	3	3	1	1	1	1	0	2	2	2	2
CO3	3	2	1	2	3	1	1	1	1	0	1	2	2	2
CO4	2	2	0	0	3	1	1	1	1	0	2	3	3	2
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			Networl			Kazem Sohraby, Daniel John Wiley, 2007.								
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Outcomessatellites and assess launch methods and technologies.2. Acquire knowledge about various multiplexing techniques used in satellite														
communication.														
3. Identify the systems required by a communications satellite to function and the trade-														
	5. Identify the systems required by a communications satellite to function and the trade- offs encountered in the design of a system.													
4. Assess the analog and digital technologies used for satellite communications networks														
and applications of those networks.														
Mapping of Course Outcomes with program outcomes														
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
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CO2	3	3	3	3	3	2	2	1	3	0	1	3	2	2
CO3	1	2	2	3	3	2	1	1	1	0	2	2	2	1
CO4	3	3	2	2	3	0	1	1	2	0	2	3	2	2
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systems	using	g small	earth s	tations	, uplink	design	, desig	n of sat	tellite li	nk for	specifie	ed (C/N	J).	
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Modula	ntion,	multi	plexing	, mult	iple ac	cess te	chniqu	es: FM	1 modu	lation,	analog	FM tr	ansmis	sion by
satellite	, S/N	ratio	for sate	ellite F	M vide	eo tran	smissic	on; dig	ital trar	nsmissi	on, bas	seband	and ba	andpass
transmi	ssion	of dig	gital da	ta, dig	ital mo	dulatio	on: BP	SK, Q	PSK; r	nultiple	exing:	FDM,	TDM;	access
techniqu	les: F	DMA,	TDMA	, CDM	IA.									



4.Satellite Communication

1978

2006.

McGraw-Hill, 4th Edition

Uni	it-IV	12 hrs									
Propagation effects and satellite services : Quantifying attenuation and depolarization, atmospheric absorption, cloud attenuation, rain and ice effects, prediction of rain attenuation. VSAT technology, direct broadcast satellite (DBS) for TV and radio, satellite navigation and GPS system, mobile satellite services.											
RECOMMENDED BOOKS											
Title	Author	Publisher									
1.Satellite Communications	Timothy Pratt, Charles W. Bostian, Jeremy Allnutt	John Wiley & Sons, 2002									
2.Satellite Communications Systems: Systems, Techniques and Technology	Gerard Maral, Michel Bousquet	John Wiley & Sons Ltd, 2002									
3. Communication satellite systems	J Martin	Prentice Hall publication,									

Dennis Roddy

Department of Electronics & Communication



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					3)		0			3	
			Sessi	onal M	larks								50	
			End	Semest	ter Exa	aminati	ion Ma	arks				5	50	
Course O) bjecti	ves	The c	course a	aims to	presen	t the p	rincip	les and t	techniqu	es of C	MOS ba	sed dig	ital
			the fu	ındame cteristi	ental de	evice ph	ysics,	proces	ssing teo	c design chniques oth in th	s and tra	insistor	level	ts with
Course Outcome: 1. Understand and appreciate the basic physics of MOS transistor, and importation of various design parameter. 2. Analyze the DC and static behavior of basic CMOS logic circuits. 3. Understand the basics of CMOS fabrication process, its requirements a challenges. 4. Calculate and optimize the performance metrics of CMOS circuits. Mapping of Course Outcomes with program outcomes														
	PO1	PO2	PO3	PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	2	2	2	2	2	0	1	1	0	0	1	2	1	1
CO2	3	3	3	3	3	2	1	1	3	2	1	2	2	2
CO3	3	2	2	3	3	2	1	1	1	2	2	2	1	2
CO4	3	3	2	3	3	0	1	1	2	1	3	2	2	3
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Introducti representa Threshold Capacitor	ation. F l voltag	Physica ge, bod	l repre y effec	sentati t. MOS	on MC device nt steer	OS trans e design ring cire	sistor t n equat	heory	NMOS	S and Pl	MOS er	hancen	nent trai	nsistor. , MOS
			100.			<u>nit-II</u>		<u> </u>	1 116	<u></u>		1		16 hrs
The comp													MOS 1	verter,
Tristate in	iverter.	Comp	arison			it-III	lodes,	BICM	05 mv	erters, P	ass tran	sistors		8 hrs
Review of Interconne prevention	ect and				echnol	ogy an				0.		-	-	rocess.
					Un	it-IV								8 hrs
Circuit cl characteri CMOS lo	stics, C	CMOS		1						-				0
					RE	COMM	IENDI	ED BO	OKS					
		r ·	Fitle					Auth	or			Publish	er	
1. Des														

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Dilip Kumar



2. Microelectronics Circuits	Sedra & Smith	Oxford University Press
3. Principles of CMOS VLSI Design	Neil H.E Weste	John Wiley, 1994
4. CMOS Digital Integrated Circuits	Sung-Mo Kang	McGraw-Hill, 2003



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					Fibr	e Opti	cs Com	munic	ations				<u> </u>	
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<u>Course</u>					-				-	-			cation	system
Outcon	nes		•					-		munica	•		1.0	
					-					d by us	ing opt	ical am	plifier.	
4. Describe the various optical network topologies.														
5. Use the appropriate state-of-the-art engineering references and resources needed to find the best solutions to optical system design problems.														
		1								m outco		1	1	
	201	PO2	PO3	PO4	PO5	PO6	P07	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2
CO1	2	2	3	3	3	0	2	1	0	0	1	3	2	3
CO2	3	3	3	3	3	2	0	1	2	0	2	3	2	2
СОЗ	3	3	2	2	3	0	1	1	2	0	0	3	2	2
CO4	3	3	3	3	2	1	2	1	2	0	3	3	1	1
CO5	3	3	3	3	3	1	0	1	2	0	3	3	2	3
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Introdu	ictior	to fibe	er optic	:: Histo	rical of			olock di	iagram	of fiber	optica	l comm	unicati	
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phase modulation, four wave mixing

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Sarbjeet Singh

Dilip Kumar



<u>Unit-III</u>

12 hrs

Optical source: Energy bands, intrinsic and extrinsic material, P-n junction, direct and indirect band gaps, LED, structure, material, quantum efficiency, power and modulation, LASER diodes, principle of operation, laser diode rate equations, quantum efficiency, structure and modulation.

Optical receivers: Principle of PIN photo detector and avalanche photodiode, photo detector noise, detector response time, RAPD, avalanche multiplication noise, temperature effects, comparison of photo detectors.

<u>Unit-IV</u>

12 hrs

Optical amplification: Introduction to optical amplifier, characteristics of semiconductor optical amplifiers (SOAs), Erbium doped fibre amplifiers (EDFAs) and Raman amplifier and their gain characteristics and gain saturation.

Optical networking: fibre optics topologies, fibre distributed data interface (FDDI) structure, synchronous optical network (SONET) and SDH, SONET Ring, networking components.

REC	OMMENDED BOOKS	
Title	Author	Publisher
1. Fiber-Optic Communication Systems	G. P. Aggarwal	J. Wiley & Sons. 2 nd Ed., 1997
2. Optic Communication Systems	Mynbaev	Pearson education, 2001,
3.Optical Fiber Communication	Gerd Keiser	McGraw Hill, 5 th edition 2013
4. Optical Fiber Communication	Senior	PHI

Department of Electronics & Communication

Vivek Harshey Sarbjeet Singh Dilip Kumar



	PEEC-722B Electronic Measurements and Instrumentation													
Electronic Measurements and Instrumentation L T P Credits														
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	<u>ctives</u>						•					scusses		
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Outc	omes						-				rument			
						dge th	eory,	workii	ng of	A/D ar	nd D/A	conver	ters and	d their
applications.														
4. Describe the working of CRO, signal generators and analyser's and apply for														
measurements Mapping of Course Outcomes with Program Outcomes														
	PO1	PO2	PO3											
CO1	1	2	0	1	2	2	0	1	0	0	0	2	2	1
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CO3	0	3	2	1	2	2	0	1	0	0	1	2	2	1
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and phase by CRO, oscilloscope probes, oscilloscope specifications and performance. Signal generator, analyser and recorders: sine wave, non-sinusoidal signal and function generators,														
frequency synthesis techniques and digital signal generators, spectrum analyzer and distortion,														
concept of ECG, EMI, EMC, and EEG etc, X-Y recorders, plotters.														
			·						-					



RECOMMENDED BOOKS											
Title	Author	Publisher									
1. Electronic Instrumentation and Measurements	David A. Bell	2nd Ed., PHI, New Delhi,2008									
2.Electronic Measurements and instrumentation.	Oliver and Cage	ТМН, 2009									

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					Nouna		EEC 72		Logio						
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~			engineer	<u> </u>											
<u>Course</u> 1. Understand the principle of artificial intelligence and its realization using artificial															
Outcomesneural networks.2. Describe the working of multilayer feed-forward artificial neural network as															
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				-	roblem			1							
					the con	-	•	-		mahlan	•				
				Apply fuzzy logic system to solve real-world problems. Mapping of Course Outcomes with program outcomes											
	PO1	PO2		PO4	PO5	PO6	PO7	PO8	PO9	PO10	PO11	PO12	PSO1	PSO2	
CO1	2	2	2	3	3	1	1	0	0	0	3	3	3	3	
01	2	2	2	5	5	1	1	U	U	0	5	5	5	3	
CO2	3	3	2	1	3	2	1	1	1	3	3	3	3	3	
CO3	2	3	2	2	2	0	0	1	1	2	2	3	3	3	
CO4	3	2	2	1	3	0	0	3	2	1	2	3	3	3	
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cartesian product, operations on fuzzy relations.															
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deruzz	meati	on me	thods and	u iuzzy	cruise-	-contro	her des	ign.							



R	RECOMMENDED BOOKS											
Title	Author	Publisher										
1. Understanding Neural Networks	Stamatios V. Kartalopoulos	Prentice Hall of India										
and Fuzzy Logic		Private Limited, New Delhi,										
		2000										
2. Fuzzy Systems Design	Riza C.	Chand Publishers										
3. Neural Networks, Fuzzy Logics	S. Rajasekaran,	PHI Learning Private										
and Genetic Algorithms (Synthesis	G.A. VijaylakshmiPai	Limited, 2011										
and Applications).												



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			economic, environmental, and social contexts and to set them for future recruitment by											
		potential employers. Identify and apply appropriate well-rehearsed note-taking interactive												
		and time management strategies to their academic studies. Develop audience-centred												
		presentations meeting concrete professional objectives and integrating ethical and legal												
		visual aids. Identify and critically evaluate the quality of claims, explanation, support, and												
	delivery in public and professional discourse, and understand the factors influencing a speaker's credibility.													
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CO2	3	3	3	2	2	1	2	3	2	2	3	0	3	3
CO3	2	2	2	3	2	2	2	3	3	3	3	2	1	2
CO4	3	3	3	3	3	3	0	3	2	3	2	3	1	2
CO5	3	3	3	3	3	2	3	2	2	2	3	3	1	3

Dilip Kumar J.S. Ubhi